

# Power Factor Controller, High-Efficiency, Enhanced for Lighting

## NCL2801

The 8-pin PFC controller NCL2801 is designed to drive PFC boost stages. It is based on an innovative Valley Count Frequency Fold-back (VCFF) method. The circuit classically operates in Critical conduction Mode (CrM) for high load values. When the load decreases a Discontinuous Conduction Mode DCM is forced by forcing a dead time which, by construction corresponds to a fixed number of valleys. The lower the output power, the higher the number of valleys corresponding to the dead time. After DCM works down to 6<sup>th</sup> valley switching and if the load continues to decrease, a dead time is continuously added to the 6<sup>th</sup> valley. The end of additional dead time is synchronized with the drain voltage valley. The maximum switching period is limited to 36.5  $\mu$ s. VCFF maximizes the efficiency during DCM and light load. In particular, the stand-by losses are reduced to a minimum. Like in FCCrM controllers, internal circuitry allows near-unity power factor even when the switching frequency is reduced. Housed in a SO-8 package, the circuit also incorporates the features necessary for robust and compact PFC stages, with few external components.

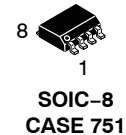
### General Features

- Near-Unity Power Factor
- Critical Conduction Mode (CrM)
- Valley Count Frequency Fold-Back (VCFF)
- Peak Current Control Mode to Maintain a Proper Current Shaping in VCFF Mode
- Fast Line / Load Transient Compensation (*Dynamic Response Enhancer*) Option
- Brown-out Detection
- Two-level Line Feed-Forward (HL&LL)
- Valley Turn-on (No Valley Hopping by Construction)
- High Drive Capability: -500 mA / +800 mA
- V<sub>CC</sub> Range: from 10.5 V to 27 V
- Low Start-up Consumption for :
- [\*C\*]& [\*D\*] Option: Low V<sub>CC</sub> Start-up Level (12.5 V)
- [\*A\*]& [\*B\*] Option: High V<sub>CC</sub> Start-up Level (17.0 V)
- [\*E\*]& [\*F\*] Option: High V<sub>CC</sub> Start-up Level (10.5 V)
- This is a Pb-Free Device

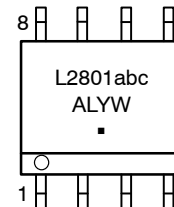


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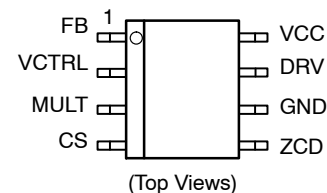


### MARKING DIAGRAMS



L2801abc = Specific Device Code  
A = Assembly Location  
L = Wafer Lot  
Y = Year  
W = Work Week  
▪ = Pb-Free Package

### PIN CONNECTIONS



### ORDERING INFORMATION

See detailed ordering and shipping information on page 25 of this data sheet.

# NCL2801

## Safety Features

- Thermal Shutdown
- Non-latching, Over-Voltage Protection (3 Prog Levels)
- Over Current Limitation
- Low Duty-Cycle Operation if the Bypass Diode is Shorted
- Open Ground Pin Fault Monitoring
- Pin CS shorted to GND or open Monitoring
- Pin ZCD open tested before controller starts
- Controller not allowed to start if MULT pin is left open

## Typical Applications

- PC Power Supplies
  - Lighting Ballasts (LED, Fluorescent)
  - Flat TV
  - All Off Line Appliances Requiring Power Factor Correction
- Several product configurations coded with three letters (L<sub>1</sub>, L<sub>2</sub>, L<sub>3</sub>) marked on the package will be available

**Table 1. NCL2801 1<sup>ST</sup> LETTER CODING OF PRODUCT VERSIONS**

| L <sub>1</sub> | Soft OVP (% of V <sub>REF</sub> ) | Fast OVP (% of V <sub>REF</sub> ) |
|----------------|-----------------------------------|-----------------------------------|
| A              | Disabled                          | 112.5                             |
| B              | Disabled                          | 110.0                             |
| C (default)    | 105.0                             | 107.0                             |

1. The NCL2801 SO8 package is marked L<sub>1</sub>L<sub>2</sub>L<sub>3</sub>

**Table 2. NCL2801 2<sup>ND</sup> LETTER CODING OF PRODUCT VERSIONS**

| L <sub>2</sub> | VCC Startup Level (V) | DRE (After Startup) | DRE (During Startup) |
|----------------|-----------------------|---------------------|----------------------|
| A              | 17.0                  | NO                  | YES                  |
| B              | 17.0                  | YES                 | YES                  |
| C              | 12.5                  | NO                  | YES                  |
| D (default)    | 12.5                  | YES                 | YES                  |
| E              | 10.5                  | NO                  | YES                  |
| F              | 10.5                  | YES                 | YES                  |

2. The NCL2801 SO8 package is marked L<sub>1</sub>L<sub>2</sub>L<sub>3</sub>

**Table 3. NCL2801 3<sup>RD</sup> LETTER CODING OF PRODUCT VERSIONS**

| L <sub>3</sub> | Brown-in & Brown-out | Line Range Detection w/ 2-level Line Feed-Forward |
|----------------|----------------------|---------------------------------------------------|
| A (default)    | YES                  | YES                                               |
| B              | YES                  | NO                                                |
| C              | NO                   | YES                                               |
| D              | NO                   | NO                                                |

# NCL2801

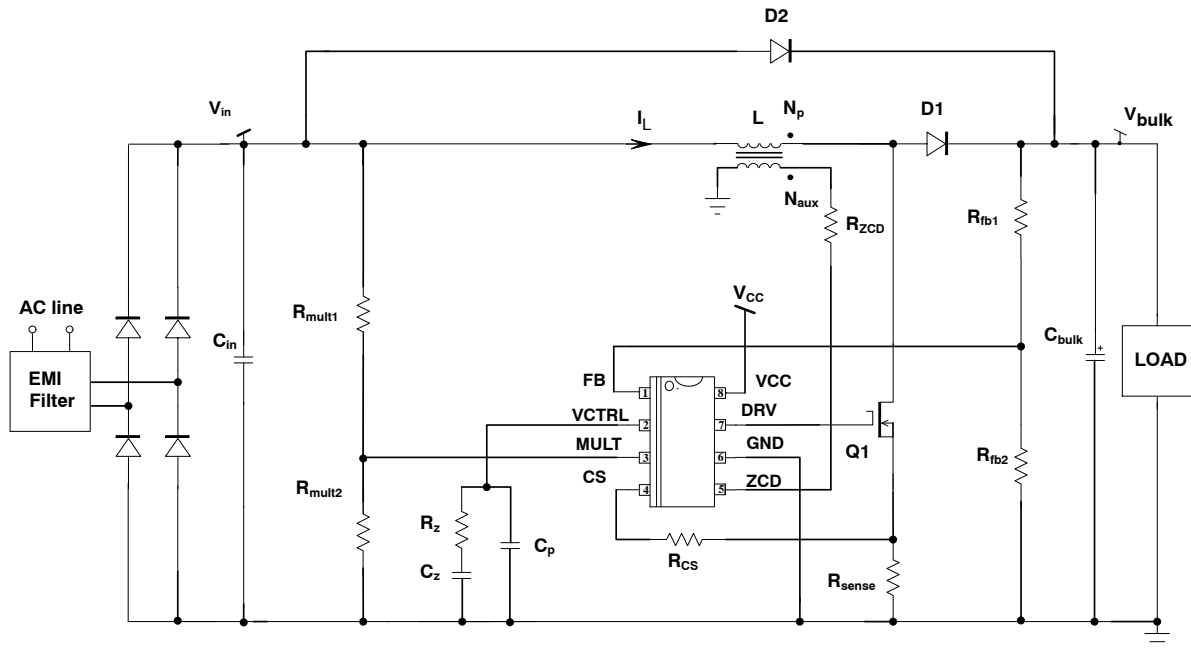


Figure 1. NCL2801 Application Schematic

Table 4. NCL2801 3RD LETTER CODING OF PRODUCT VERSIONS

| Pin Number | Name  | Function                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                         |
|------------|-------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1          | FB    | This pin receives a portion of the PFC output voltage for the regulation and the optional Dynamic Response Enhancer (DRE) that drastically speeds-up the loop response when the output voltage drops below 95.5 % of the desired output level.<br>FB pin voltage $V_{FB}$ is also the input signal for the (non-latching) Over-Voltage (OVP). The UVP comparator prevents operation as long as FB pin voltage is lower than $V_{UVPH}$ internal voltage reference. A SOFTOVP comparator gradually reduces the duty-ratio when FB pin voltage exceeds 105% of $V_{REF}$ (option dependent). If despite of this, the output voltage still increases, the driver is immediately disabled by fast OVP if the output voltage exceeds x% of the desired level (option dependent).. A 250-nA sink current is built-in to trigger the UVP protection and disable the part if the feedback pin is accidentally left open. |
| 2          | VCTRL | The error amplifier output is available on this pin. The network connected between this pin and ground adjusts the regulation loop bandwidth that is typically set below 20 Hz to achieve high Power Factor ratios.<br>VCTRL pin is internally pulled down when the circuit is off so that when it starts operation, the power increases slowly to provide a soft-start function.<br>VCTRL pin must not be controlled or pulled down externally.<br>Pulled to GND if BO and at startup (pseudo-soft start). Just a switch.                                                                                                                                                                                                                                                                                                                                                                                       |
| 3          | MULT  | Multiplier input pin. This pin receives a scaled down rectified mains voltage by the means of a resistor voltage divider connected between $V_{in}$ and GND.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     |
| 4          | CS    | This pin senses the MOSFET current in order to end the on-time when the current reaches the control value or the maximum current limit.<br>Just before startup, the value of the resistance between CS pin and GND pin is sensed for determining the VCTRL value of the CrM to DCM threshold.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    |
| 5          | ZCD   | This pin uses the auxiliary winding voltage to determine the inductor current zero crossing.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     |
| 6          | GND   | Connect this pin to the PFC stage ground.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |
| 7          | DRV   | The high-current capability of the totem pole gate drive (-0.5/+0.8 A) makes it suitable to effectively drive high gate charge power MOSFETs.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    |
| 8          | VCC   | This pin is the positive supply of the IC. The circuit starts to operate when VCC exceeds 17.0 V ([*A*] & [*B*] Versions) or 12.5 V ([*C*] & [*D*] Versions) or 10.5 V ([*E*] & [*F*] Options) and turns off when VCC goes below 10.0 V (typ) for [*C*] & [*D*] Options and below 9.0 V (typ) for [*A*] & [*B*] & [*E*] & [*F*] Options. After start-up, the operating range is 10.0 V (or 9 V depending on option) up to 27 V.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  |

Table 5. MAXIMUM RATINGS TABLE

| Symbol                             | Pin | Rating                                                                                                                                  | Value                                         | Unit       |
|------------------------------------|-----|-----------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------|------------|
| FB                                 | 1   | Feedback Pin                                                                                                                            | -0.3, +9                                      | V          |
| VCTRL                              | 2   | V <sub>CONTROL</sub> pin                                                                                                                | -0.3, V <sub>ctrl,max</sub><br>(Note 3)       | V          |
| MULT                               | 3   | Multiplier Input pin                                                                                                                    | -0.3, +9                                      | V          |
| CS                                 | 4   | CS Pin                                                                                                                                  | -0.3, +9                                      | V          |
| ZCD                                | 5   | ZCD Pin                                                                                                                                 | -0.3, V <sub>CC</sub> +0.3                    | V          |
| DRV                                | 7   | Driver Voltage<br>Driver Current                                                                                                        | -0.3, V <sub>DRV</sub> (Note 3)<br>-500, +800 | V<br>mA    |
| VCC                                | 8   | Power Supply Input                                                                                                                      | -0.3, + 27                                    | V          |
| P <sub>D</sub><br>R <sub>θja</sub> |     | Power Dissipation and Thermal Characteristics<br>Maximum Power Dissipation @ T <sub>A</sub> =70°C<br>Thermal Resistance Junction to Air | 300<br>180                                    | mW<br>°C/W |
| T <sub>J</sub>                     |     | Operating Junction Temperature Range                                                                                                    | -40 to + 125                                  | °C         |
| T <sub>J,max</sub>                 |     | Maximum Junction Temperature                                                                                                            | 150                                           | °C         |
| T <sub>S,max</sub>                 |     | Storage Temperature Range                                                                                                               | -65 to 150                                    | °C         |
| T <sub>L,max</sub>                 |     | Lead Temperature (Soldering, 10s)                                                                                                       | 300                                           | °C         |
| MSL                                |     | Moisture Sensitivity Level                                                                                                              | 1                                             | -          |
|                                    |     | ESD Capability, HBM model (Note 4)                                                                                                      | > 2000                                        | V          |
|                                    |     | ESD Capability, Machine Model (Note 4)                                                                                                  | > 200                                         | V          |
|                                    |     | ESD,CDM                                                                                                                                 | 1000                                          | V          |

3. "V<sub>ctrl,max</sub>" is the VCTRL pin clamp voltage. "V<sub>DRV</sub>" is the DRV clamp voltage (V<sub>DRVhigh</sub>) if V<sub>CC</sub> is higher than (V<sub>DRVhigh</sub>). "V<sub>DRV</sub>" is V<sub>CC</sub> otherwise.

4. This device(s) contains ESD protection and exceeds the following tests: Human Body Model 2000 V per JEDEC Standard JESD22-A114E Machine Model Method 200 V per JEDEC Standard JESD22-A115-A

5. This device contains latch-up protection and exceeds 100 mA per JEDEC Standard JESD78.

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

**Table 6. ELECTRICAL CHARACTERISTICS** (Conditions:  $V_{CC} = 18\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise specified) (Note 6)

| Symbol                             | Rating                                                                                                                                   | Min                  | Typ                   | Max                    | Unit          |
|------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------|----------------------|-----------------------|------------------------|---------------|
| <b>START-UP AND SUPPLY CIRCUIT</b> |                                                                                                                                          |                      |                       |                        |               |
| $V_{CC,on}$                        | Start-Up Threshold, $V_{CC}$ increasing:<br>[*E*] & [*F*] Versions<br>[*C*] & [*D*] Versions<br>[*A*] & [*B*] Versions                   | 9.75<br>11.6<br>15.6 | 10.5<br>12.50<br>16.7 | 11.25<br>13.4<br>18.00 | V<br>V<br>V   |
| $V_{CC,off}$                       | Minimum Operating Voltage, $V_{CC}$ falling<br>[*C*] & [*D*] Versions<br>[*A*] & [*B*] & [*E*] & [*F*]                                   | 9.3<br>8.4           | 10.0<br>9.0           | 10.7<br>9.6            | V<br>V        |
| $V_{CC,rst}$                       | Voltage at which IC completely restarts<br>ICC drops to $\sim I_{CC,start}$<br>(Min and Max values are guaranteed by functional testing) | 6.50                 | 7.2                   | 7.80                   | V             |
| $V_{CC,hyst}$                      | Hysteresis ( $V_{CC,on} - V_{CC,off}$ )<br>[*E*] & [*F*] Versions<br>[*C*] & [*D*] Versions<br>[*A*] & [*B*] Versions                    | 0.75<br>1.25<br>6.00 | 1.6<br>2.5<br>7.7     | 3.0<br>3.75<br>10      | V<br>V<br>V   |
| $I_{CC,start}$                     | Start-Up Current, $V_{CC} = 9.4\text{ V}$ , below startup voltage                                                                        | 0                    | 10                    | 60                     | $\mu\text{A}$ |
| $I_{CC,op1}$                       | Operating Consumption, no switching.                                                                                                     | 0                    | 0.4                   | 1.00                   | mA            |
| $I_{CC,op2}$                       | Operating Consumption, 50-kHz switching, no load on DRV pin                                                                              | 1.0                  | 2.00                  | 3.00                   | mA            |

**GATE DRIVE**

|                |                                                                                                                                                                    |            |           |          |          |
|----------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------|-----------|----------|----------|
| $t_R$          | Output voltage rise-time @ $C_L = 1\text{ nF}$ , 10–90% of output signal                                                                                           | 15         | 30        | 90       | ns       |
| $t_F$          | Output voltage fall-time @ $C_L = 1\text{ nF}$ , 10–90% of output signal                                                                                           | 10         | 20        | 50       | ns       |
| $R_{OH}$       | Source resistance @ 200 mV under High VCC                                                                                                                          | 4          | 10        | 20       | $\Omega$ |
| $R_{OL}$       | Sink resistance @ 200mV above Low VCC                                                                                                                              | 2          | 7         | 15       | $\Omega$ |
| $V_{DRV,low}$  | DRV pin level for $V_{CC} = V_{CC,off} + 200\text{ mV}$<br>(10-k $\Omega$ resistor between DRV and GND)<br>[*A*] & [*B*] & [*E*] & [*F*]<br>[*C*] & [*D*] Versions | 8.6<br>9.6 | 9.2<br>10 | 10<br>11 | V<br>V   |
| $V_{DRV,high}$ | DRV pin level at $V_{CC} = 27\text{ V}$ ( $R_L = 33\text{ k}\Omega$ & $C_L = 1\text{ nF}$ )                                                                        | 10         | 12        | 14       | V        |
| $V_{DRV,L}$    | Maximum DRV voltage while forcing zero at DRV pin and injecting 10 mA into DRV pin @ $V_{CC} = 12\text{ V}$                                                        | 0          | 100       | 200      | mV       |

**REGULATION BLOCK**

|                             |                                                                                                                                                                         |            |            |            |               |
|-----------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------|------------|------------|---------------|
| $V_{REF}$                   | Feedback Voltage Reference                                                                                                                                              | 2.45       | 2.50       | 2.55       | V             |
| $I_{EA}$                    | Error Amplifier Current Capability (source and sink)                                                                                                                    | 15         | 20         | 25         | $\mu\text{A}$ |
| $G_{EA}$                    | Error Amplifier Gain                                                                                                                                                    | 110        | 200        | 290        | $\mu\text{S}$ |
| $V_{ctrl,max} V_{ctrl,min}$ | $V_{CTRL}$ pin Voltage ( $V_{ctrl}$ ):<br>– @ $V_{FB} = 2\text{ V}$ (OTA is sourcing 20 $\mu\text{A}$ )<br>– @ $V_{FB} = 3\text{ V}$ (OTA is sinking 20 $\mu\text{A}$ ) | 4.4<br>0.4 | 4.5<br>0.5 | 4.6<br>0.6 | V             |

**CURRENT SENSE BLOCK**

|                       |                                                                                                                           |      |      |      |   |
|-----------------------|---------------------------------------------------------------------------------------------------------------------------|------|------|------|---|
| $V_{CS\_OCP(th)}$     | Current Sense Voltage Reference for option w/o line level detection<br>[**B]&[**D] Options<br>At $t_{LEB,OCP}$            | 0.97 | 1.07 | 1.19 | V |
| $V_{CS\_OVS(th)}$     | Current Sense Overstress Voltage Reference for option w/o line level detection<br>[**B]&[**D] Options<br>At $t_{LEB,OVS}$ | 1.45 | 1.60 | 1.78 | V |
| $V_{CS\_OCP\_LL(th)}$ | Current Sense Voltage Reference when Low Line is detected<br>[**A]&[**C] Options<br>At $t_{LEB,OCP}$                      | 0.97 | 1.07 | 1.19 | V |
| $V_{CS\_OVS\_LL(th)}$ | Current Sense Overstress Voltage Reference when Low Line is detected<br>[**A]&[**C] Options<br>At $t_{LEB,OVS}$           | 1.45 | 1.60 | 1.78 | V |

**Table 6. ELECTRICAL CHARACTERISTICS** (Conditions:  $V_{CC} = 18\text{ V}$ ,  $T_J = -40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ , unless otherwise specified) (Note 6)

| Symbol                | Rating                                                                                                            | Min  | Typ  | Max  | Unit          |
|-----------------------|-------------------------------------------------------------------------------------------------------------------|------|------|------|---------------|
| $V_{CS\_OCP\_HL(th)}$ | Current Sense Voltage Reference when High Line is detected<br>[**A]&[**C] Options<br>At $t_{LEB,OCP}$             | 0.53 | 0.58 | 0.66 | V             |
| $V_{CS\_OVS\_HL(th)}$ | Current Sense Overstress Voltage Reference when High Line is detected<br>[**A]&[**C] Options<br>At $t_{LEB,OVS}$  | 0.79 | 0.87 | 0.97 | V             |
| $t_{LEB,OCP}$         | Leading edge Blanking Time for current control                                                                    | 125  | 200  | 275  | ns            |
| $t_{LEB,OVS}$         | Leading edge Blanking Time for Overstress                                                                         | 50   | 100  | 150  | ns            |
| $t_{OCP}$             | Over-Current Protection Delay from $V_{CS} > V_{CS(th)}$ to<br>DRV low<br>Test: $V_{CS} > V_{CS} + 100\text{ mV}$ | 10   | 40   | 200  | ns            |
| $t_{WDG(OS)}$         | Watch Dog Timer in "OverStress" Situation                                                                         | 400  | 800  | 1200 | $\mu\text{s}$ |

**ZERO CURRENT DETECTION BLOCK**

|                    |                                                                         |      |      |      |               |
|--------------------|-------------------------------------------------------------------------|------|------|------|---------------|
| $V_{CL(pos)}$      | ZCD positive clamp ( $V_{CC} = 12\text{ V}$ , $I_{ZCD} = 5\text{ mA}$ ) | 12.6 | 12.9 | 13.2 | V             |
| $V_{ZCD(th)H}$     | Zero Current Detection, $V_{ZCD}$ rising                                | 675  | 750  | 825  | mV            |
| $V_{ZCD(th)L}$     | Zero Current Detection, $V_{ZCD}$ falling                               | 200  | 250  | 300  | mV            |
| $V_{ZCD(hyst)}$    | Hysteresis of the Zero Current Detection Comparator                     | 375  | 500  | 625  | mV            |
| $I_{ZCD,bias}$     | ZCD pin input leakage current                                           | 0    | 250  | 500  | nA            |
| $t_{ZCD}$          | ( $V_{ZCD} < V_{ZCD(th)L}$ ) to (DRV high)                              | 20   | 80   | 200  | ns            |
| $t_{SYNC}$         | Minimum ZCD Pulse Width (Guaranteed by Design)                          | –    | 60   | –    | ns            |
| $t_{WDG}$          | Watch Dog Timer<br>If no ZCD detected                                   | 80   | 200  | 320  | $\mu\text{s}$ |
| $I_{ZCD,pu}$       | Pull-up current source to detect ZCD open pin<br>At startup only        | 0.85 | 1    | 1.15 | $\mu\text{A}$ |
| $V_{REF,ZCD,open}$ | Voltage reference to test ZCD pin short during startup                  | 150  | 200  | 250  | mV            |

**MULTIPLIER**

|                   |                                                                                                               |       |       |      |     |
|-------------------|---------------------------------------------------------------------------------------------------------------|-------|-------|------|-----|
| $K_{mult}$        | Multiplier Gain (Note 2) for option w/o line level detection<br>[**B]&[**D] Options                           | 0.34  | 0.38  | 0.42 | 1/V |
| $K_{mult,HL}$     | Multiplier Gain (Note 2) when High Line is detected<br>[**A]&[**C] Options                                    | 0.22  | 0.24  | 0.28 | 1/V |
| $K_{mult,LL}$     | Multiplier Gain (Note 2) when Low Line is detected<br>[**A]&[**C] Options                                     | 0.72  | 0.80  | 0.88 | 1/V |
| $K_{mult,Ratio}$  | Ration between $K_{mult,LL}$ and $K_{mult,HL}$<br>[**A]&[**C] Options                                         | 2.9   | 3.3   | 3.7  |     |
| $K_{offset}$      | $K_{offset} \cdot V_{ton}$ voltage added at the multiplier output<br>[**A]&[**C] Options (w/ Line Detection)  | 0.10  | 0.140 | 0.20 |     |
| $K_{offset\_nld}$ | $K_{offset} \cdot V_{ton}$ voltage added at the multiplier output<br>[**B]&[**D] Options (w/o Line Detection) | 0.040 | 0.075 | 0.12 |     |
| $I_{mult\_pd}$    | Current pull-down on Mult pin                                                                                 | 200   | 280   | 350  | nA  |
| $V_{mult\_max}$   | Maximum MULT pin voltage<br>Controller disabled if MULT pin voltage goes above this threshold                 | 2.88  | 3.2   | 3.52 | V   |

**MAXIMUM ON-TIME**

|                  |                              |     |    |     |               |
|------------------|------------------------------|-----|----|-----|---------------|
| $t_{ON,max,A,2}$ | @ $V_{CTRL} = 4.50\text{ V}$ | 26  | 30 | 36  | $\mu\text{s}$ |
| $t_{ON,max,A,1}$ | @ $V_{CTRL} = 0.55\text{ V}$ | 3.6 | 5  | 6.9 | $\mu\text{s}$ |

**Table 6. ELECTRICAL CHARACTERISTICS** (Conditions:  $V_{CC} = 18\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise specified) (Note 6)

| Symbol                                                        | Rating                                                                                                                                                                                                                                           | Min   | Typ   | Max   | Unit |
|---------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------|-------|-------|------|
| <b>R<sub>CS</sub> VALUE IDENTIFICATION REFERENCE VOLTAGES</b> |                                                                                                                                                                                                                                                  |       |       |       |      |
| $I_{RCS}$                                                     | Internal current sourced by CS pin into a 1% R <sub>CS</sub> resistor just before the startup generates a voltage drop V <sub>CS</sub>                                                                                                           | 0.96  | 1.0   | 1.04  | mA   |
| $V_{RCS,REF,1}$                                               | Internal voltage reference for identifying the R <sub>CS</sub> resistor value<br>CS pin is said shorted to GND if $V_{CS} < V_{RCS,REF,1}$                                                                                                       | 20    | 50    | 100   | mV   |
| $V_{RCS,REF,2}$                                               | Internal voltage reference for identifying the R <sub>CS</sub> resistor value<br>$R_{CS} = 150\ \Omega$ if $R_{CS,REF,1} < V_{CS} < V_{RCS,REF,2}$                                                                                               | 180   | 230   | 280   | mV   |
| $V_{RCS,REF,3}$                                               | Internal voltage reference for identifying the R <sub>CS</sub> resistor value<br>$R_{CS} = 330\ \Omega$ if $V_{RCS,REF,2} < V_{CS} < V_{RCS,REF,3}$                                                                                              | 400   | 460   | 530   | mV   |
| $V_{RCS,REF,4}$                                               | Internal voltage reference for identifying the R <sub>CS</sub> resistor value<br>$R_{CS} = 620\ \Omega$ if $V_{RCS,REF,3} < V_{CS} < V_{RCS,REF,4}$                                                                                              | 720   | 790   | 880   | mV   |
| $V_{RCS,REF,5}$                                               | Internal voltage reference for identifying the R <sub>CS</sub> resistor value<br>$R_{CS} = 1000\ \Omega$ if $V_{RCS,REF,4} < V_{CS} < V_{RCS,REF,5}$<br>CS pin open if $V_{CS} > V_{RCS,REF,5}$<br>RCS open do not allow the controller to start | 1190  | 1300  | 1400  | mV   |
| <b>FREQUENCY FOLDBACK THRESHOLDS &amp; HYSTERESIS</b>         |                                                                                                                                                                                                                                                  |       |       |       |      |
| $V_{CTRL,th,12,1000}$                                         | V <sub>CTRL</sub> threshold for valley1 to valley2 forcing @R <sub>CS</sub> = 1000 $\Omega$                                                                                                                                                      | 1.971 | 2.19  | 2.409 | V    |
| $V_{CTRL,th,23,1000}$                                         | V <sub>CTRL</sub> threshold for valley2 to valley3 forcing @R <sub>CS</sub> = 1000 $\Omega$                                                                                                                                                      | 1.647 | 1.83  | 2.013 | V    |
| $V_{CTRL,th,34,1000}$                                         | V <sub>CTRL</sub> threshold for valley3 to valley4 forcing @R <sub>CS</sub> = 1000 $\Omega$                                                                                                                                                      | 1.332 | 1.48  | 1.628 | V    |
| $V_{CTRL,th,45,1000}$                                         | V <sub>CTRL</sub> threshold for valley4 to valley5 forcing @R <sub>CS</sub> = 1000 $\Omega$                                                                                                                                                      | 1.008 | 1.12  | 1.232 | V    |
| $V_{CTRL,th,56,1000}$                                         | V <sub>CTRL</sub> threshold for valley5 to valley6 forcing @R <sub>CS</sub> = 1000 $\Omega$                                                                                                                                                      | 0.693 | 0.77  | 0.847 | V    |
| $V_{CTRL,th,65,1000}$                                         | V <sub>CTRL</sub> threshold for valley6 to valley5 forcing @R <sub>CS</sub> = 1000 $\Omega$                                                                                                                                                      | 1.008 | 1.12  | 1.232 | V    |
| $V_{CTRL,th,54,1000}$                                         | V <sub>CTRL</sub> threshold for valley5 to valley4 forcing @R <sub>CS</sub> = 1000 $\Omega$                                                                                                                                                      | 1.332 | 1.48  | 1.628 | V    |
| $V_{CTRL,th,43,1000}$                                         | V <sub>CTRL</sub> threshold for valley4 to valley3 forcing @R <sub>CS</sub> = 1000 $\Omega$                                                                                                                                                      | 1.647 | 1.83  | 2.013 | V    |
| $V_{CTRL,th,32,1000}$                                         | V <sub>CTRL</sub> threshold for valley3 to valley2 forcing @R <sub>CS</sub> = 1000 $\Omega$                                                                                                                                                      | 1.971 | 2.19  | 2.409 | V    |
| $V_{CTRL,th,21,1000}$                                         | V <sub>CTRL</sub> threshold for valley2 to valley1 forcing @R <sub>CS</sub> = 1000 $\Omega$                                                                                                                                                      | 2.286 | 2.54  | 2.794 | V    |
| $V_{CTRL,hyst,1000}$                                          | V <sub>CTRL</sub> hysteresis when changing forced valley @R <sub>CS</sub> = 1000 $\Omega$                                                                                                                                                        | 300   | 356   | 420   | mV   |
| $V_{CTRL,th,12,620}$                                          | V <sub>CTRL</sub> threshold for valley1 to valley2 forcing @R <sub>CS</sub> = 620 $\Omega$                                                                                                                                                       | 1.647 | 1.830 | 2.013 | V    |
| $V_{CTRL,th,23,620}$                                          | V <sub>CTRL</sub> threshold for valley2 to valley3 forcing @R <sub>CS</sub> = 620 $\Omega$                                                                                                                                                       | 1.413 | 1.570 | 1.727 | V    |
| $V_{CTRL,th,34,620}$                                          | V <sub>CTRL</sub> threshold for valley3 to valley4 forcing @R <sub>CS</sub> = 620 $\Omega$                                                                                                                                                       | 1.170 | 1.300 | 1.430 | V    |
| $V_{CTRL,th,45,620}$                                          | V <sub>CTRL</sub> threshold for valley4 to valley5 forcing @R <sub>CS</sub> = 620 $\Omega$                                                                                                                                                       | 0.927 | 1.030 | 1.133 | V    |
| $V_{CTRL,th,56,620}$                                          | V <sub>CTRL</sub> threshold for valley5 to valley6 forcing @R <sub>CS</sub> = 620 $\Omega$                                                                                                                                                       | 0.693 | 0.770 | 0.847 | V    |
| $V_{CTRL,th,65,620}$                                          | V <sub>CTRL</sub> threshold for valley6 to valley5 forcing @R <sub>CS</sub> = 620 $\Omega$                                                                                                                                                       | 0.927 | 1.030 | 1.133 | V    |
| $V_{CTRL,th,54,620}$                                          | V <sub>CTRL</sub> threshold for valley5 to valley4 forcing @R <sub>CS</sub> = 620 $\Omega$                                                                                                                                                       | 1.170 | 1.300 | 1.430 | V    |
| $V_{CTRL,th,43,620}$                                          | V <sub>CTRL</sub> threshold for valley4 to valley3 forcing @R <sub>CS</sub> = 620 $\Omega$                                                                                                                                                       | 1.413 | 1.570 | 1.727 | V    |
| $V_{CTRL,th,32,620}$                                          | V <sub>CTRL</sub> threshold for valley3 to valley2 forcing @R <sub>CS</sub> = 620 $\Omega$                                                                                                                                                       | 1.647 | 1.830 | 2.013 | V    |
| $V_{CTRL,th,21,620}$                                          | V <sub>CTRL</sub> threshold for valley2 to valley1 forcing @R <sub>CS</sub> = 620 $\Omega$                                                                                                                                                       | 1.890 | 2.100 | 2.310 | V    |
| $V_{CTRL,hyst,620}$                                           | V <sub>CTRL</sub> hysteresis when changing forced valley @R <sub>CS</sub> = 620 $\Omega$                                                                                                                                                         | 200   | 267   | 320   | mV   |
| $V_{CTRL,th,12,330}$                                          | V <sub>CTRL</sub> threshold for valley1 to valley2 forcing @R <sub>CS</sub> = 330 $\Omega$                                                                                                                                                       | 1.332 | 1.480 | 1.628 | V    |
| $V_{CTRL,th,23,330}$                                          | V <sub>CTRL</sub> threshold for valley2 to valley3 forcing @R <sub>CS</sub> = 330 $\Omega$                                                                                                                                                       | 1.170 | 1.300 | 1.430 | V    |
| $V_{CTRL,th,34,330}$                                          | V <sub>CTRL</sub> threshold for valley3 to valley4 forcing @R <sub>CS</sub> = 330 $\Omega$                                                                                                                                                       | 1.008 | 1.120 | 1.232 | V    |
| $V_{CTRL,th,45,330}$                                          | V <sub>CTRL</sub> threshold for valley4 to valley5 forcing @R <sub>CS</sub> = 330 $\Omega$                                                                                                                                                       | 0.846 | 0.940 | 1.034 | V    |

# NCL2801

**Table 6. ELECTRICAL CHARACTERISTICS** (Conditions:  $V_{CC} = 18\text{ V}$ ,  $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise specified) (Note 6)

| Symbol               | Rating                                                                       | Min   | Typ   | Max   | Unit |
|----------------------|------------------------------------------------------------------------------|-------|-------|-------|------|
| $V_{CTRL,th,56,330}$ | $V_{CTRL}$ threshold for valley5 to valley6 forcing @ $R_{CS} = 330\ \Omega$ | 0.693 | 0.770 | 0.847 | V    |
| $V_{CTRL,th,65,330}$ | $V_{CTRL}$ threshold for valley6 to valley5 forcing @ $R_{CS} = 330\ \Omega$ | 0.846 | 0.940 | 1.034 | V    |
| $V_{CTRL,th,54,330}$ | $V_{CTRL}$ threshold for valley5 to valley4 forcing @ $R_{CS} = 330\ \Omega$ | 1.008 | 1.120 | 1.232 | V    |
| $V_{CTRL,th,43,330}$ | $V_{CTRL}$ threshold for valley4 to valley3 forcing @ $R_{CS} = 330\ \Omega$ | 1.170 | 1.300 | 1.430 | V    |
| $V_{CTRL,th,32,330}$ | $V_{CTRL}$ threshold for valley3 to valley2 forcing @ $R_{CS} = 330\ \Omega$ | 1.332 | 1.480 | 1.628 | V    |
| $V_{CTRL,th,21,330}$ | $V_{CTRL}$ threshold for valley2 to valley1 forcing @ $R_{CS} = 330\ \Omega$ | 1.494 | 1.660 | 1.826 | V    |
| $V_{CTRL,hyst,330}$  | $V_{CTRL}$ hysteresis when changing forced valley @ $R_{CS} = 330\ \Omega$   | 120   | 178   | 230   | mV   |
|                      |                                                                              |       |       |       |      |
| $V_{CTRL,th,12,150}$ | $V_{CTRL}$ threshold for valley1 to valley2 forcing @ $R_{CS} = 150\ \Omega$ | 1.008 | 1.120 | 1.232 | V    |
| $V_{CTRL,th,23,150}$ | $V_{CTRL}$ threshold for valley2 to valley3 forcing @ $R_{CS} = 150\ \Omega$ | 0.927 | 1.030 | 1.133 | V    |
| $V_{CTRL,th,34,150}$ | $V_{CTRL}$ threshold for valley3 to valley4 forcing @ $R_{CS} = 150\ \Omega$ | 0.846 | 0.940 | 1.034 | V    |
| $V_{CTRL,th,45,150}$ | $V_{CTRL}$ threshold for valley4 to valley5 forcing @ $R_{CS} = 150\ \Omega$ | 0.774 | 0.860 | 0.946 | V    |
| $V_{CTRL,th,56,150}$ | $V_{CTRL}$ threshold for valley5 to valley6 forcing @ $R_{CS} = 150\ \Omega$ | 0.693 | 0.770 | 0.847 | V    |
| $V_{CTRL,th,65,150}$ | $V_{CTRL}$ threshold for valley6 to valley5 forcing @ $R_{CS} = 150\ \Omega$ | 0.774 | 0.860 | 0.946 | V    |
| $V_{CTRL,th,54,150}$ | $V_{CTRL}$ threshold for valley5 to valley4 forcing @ $R_{CS} = 150\ \Omega$ | 0.846 | 0.940 | 1.034 | V    |
| $V_{CTRL,th,43,150}$ | $V_{CTRL}$ threshold for valley4 to valley3 forcing @ $R_{CS} = 150\ \Omega$ | 0.927 | 1.030 | 1.133 | V    |
| $V_{CTRL,th,32,150}$ | $V_{CTRL}$ threshold for valley3 to valley2 forcing @ $R_{CS} = 150\ \Omega$ | 1.008 | 1.120 | 1.232 | V    |
| $V_{CTRL,th,21,150}$ | $V_{CTRL}$ threshold for valley2 to valley1 forcing @ $R_{CS} = 150\ \Omega$ | 1.089 | 1.210 | 1.331 | V    |
| $V_{CTRL,hyst,150}$  | $V_{CTRL}$ hysteresis when changing forced valley @ $R_{CS} = 150\ \Omega$   | 35    | 89    | 135   | mV   |

## SWITCHING CYCLE DEAD TIME

|           |                                                                                                          |         |           |          |                                |
|-----------|----------------------------------------------------------------------------------------------------------|---------|-----------|----------|--------------------------------|
| $t_{ADT}$ | Dead time added after 6 <sup>th</sup> valley<br>$V_{ctrl} = 0.50\text{ V}$<br>$V_{ctrl} = 0.77\text{ V}$ | 14<br>0 | 20<br>0.1 | –<br>0.4 | $\mu\text{s}$<br>$\mu\text{s}$ |
|-----------|----------------------------------------------------------------------------------------------------------|---------|-----------|----------|--------------------------------|

## FEED-BACK OVER AND UNDER-VOLTAGE PROTECTIONS (OVP)

|                     |                                                                                                                                        |       |       |       |    |
|---------------------|----------------------------------------------------------------------------------------------------------------------------------------|-------|-------|-------|----|
| $R_{softOVP,C}$     | Ratio (Soft OVP Threshold, $V_{FB}$ rising) over $V_{REF}$ (Options [C**])                                                             | 103.5 | 105   | 106.5 | %  |
| $R_{softOVP(HYST)}$ | Ratio (Soft OVP Hysteresis) over $V_{REF}$                                                                                             | 0.8   | 1.3   | 3.2   | %  |
| $R_{fastOVP,A}$     | Ratio (Fast OVP Threshold, $V_{FB}$ rising) over $V_{REF}$ (Options [A**])                                                             | 108.5 | 112.5 | 116.5 | %  |
| $R_{fastOVP,B}$     | Ratio (Fast OVP Threshold, $V_{FB}$ rising) over $V_{REF}$ (Option [B**])                                                              | 106.1 | 110   | 113.9 | %  |
| $R_{fastOVP,C}$     | Ratio (Fast OVP Threshold, $V_{FB}$ rising) over $V_{REF}$ (Option [C**])                                                              | 103.2 | 107   | 110.8 | %  |
| $R_{fastOVP(HYST)}$ | Ratio (Fast OVP Hysteresis) over $V_{REF}$                                                                                             | 3.0   | 4.0   | 5.7   | %  |
| $I_{B,FB}$          | FB pin pull-down Current @ $V_{FB} = V_{OVP}$ and $V_{FB} = V_{UVP}$<br>Pulls down the FB pin in case the pin is open (solder failure) | 50    | 200   | 450   | nA |

## DYNAMIC RESPONSE ENHANCER (DRE)

|                      |                                                                                                                                                                                            |      |      |      |               |
|----------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|------|---------------|
| $R_{DRE}$            | Ratio (DRE Threshold, $V_{FB}$ falling) over $V_{REF}$                                                                                                                                     | 94.0 | 95.7 | 97.5 | %             |
| $R_{DRE(HYST)}$      | Ratio (DRE Hysteresis) over $V_{REF}$                                                                                                                                                      | 0.8  | 2.0  | 3.0  | %             |
| $I_{VCTRL,Startup}$  | Current measured out of $V_{CTRL}$ pin (DRE current source minus max OTA current)<br>@ $V_{FB}=1\text{V}$ ( $PFCOK=0 \leftrightarrow$ Startup)                                             | 80   | 100  | 120  | $\mu\text{A}$ |
| $I_{VCTRL,1,Steady}$ | Current measured out of $V_{CTRL}$ pin (DRE current source minus max OTA current)<br>@ $V_{FB}=1\text{V}$ ( $PFCOK=1 \leftrightarrow$ Steady State)<br>[*B*], [*D*], [*F*] Product Options | 160  | 200  | 240  | $\mu\text{A}$ |

## UNDER VOLTAGE PROTECTION / DISABLE

|            |                                    |     |     |     |    |
|------------|------------------------------------|-----|-----|-----|----|
| $V_{UVPH}$ | UVP Threshold, $V_{FB}$ increasing | 380 | 450 | 520 | mV |
| $V_{UVPL}$ | UVP Threshold, $V_{FB}$ decreasing | 150 | 200 | 250 | mV |

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**Table 6. ELECTRICAL CHARACTERISTICS** (Conditions: VCC = 18 V, T<sub>J</sub> = -40°C to +125°C, unless otherwise specified) (Note 6)

| Symbol                 | Rating         | Min | Typ | Max | Unit |
|------------------------|----------------|-----|-----|-----|------|
| V <sub>UVP(HYST)</sub> | UVP Hysteresis | 200 | 250 | 300 | mV   |

## BROWN-OUT PROTECTION AND LINE FEED FORWARD

|                        |                                                                                                                                                           |       |       |       |    |
|------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------|-------|-------|-------|----|
| V <sub>BOH</sub>       | Brown-In Threshold, V <sub>mains</sub> increasing<br>Note: V <sub>line,BOH,rms</sub> = 74, 80, 87 V assuming 1/K <sub>m</sub> = 144                       | 725   | 787   | 860   | mV |
| V <sub>BOL</sub>       | Brown-Out Threshold, V <sub>mains</sub> decreasing<br>Note: V <sub>line,BOL,rms</sub> = 64, 72, 78 V assuming 1/K <sub>m</sub> = 144                      | 634   | 709   | 770   | mV |
| V <sub>BO(HYST)</sub>  | Brown-Out Comparator Hysteresis                                                                                                                           | 50    | 75    | 130   | mV |
| t <sub>BO(blank)</sub> | Brown-Out Blanking Time                                                                                                                                   | 36    | 50    | 67    | ms |
| I <sub>VCTRL(BO)</sub> | VCTRL pin sink current during BO condition                                                                                                                | 20    | 30    | 42    | μA |
| V <sub>HL</sub>        | Comparator Threshold for Line Range Detection V <sub>MULT</sub> rising<br>Note: V <sub>line,HL,rms</sub> = 157,165,174 V assuming 1/K <sub>m</sub> = 144  | 1.543 | 1.625 | 1.706 | V  |
| V <sub>LL</sub>        | Comparator Threshold for Line Range Detection V <sub>MULT</sub> falling<br>Note: V <sub>line,HL,rms</sub> = 137,145,152 V assuming 1/K <sub>m</sub> = 144 | 1.350 | 1.422 | 1.493 | V  |
| V <sub>HL(hyst)</sub>  | Comparator Hysteresis for Line Range Detection                                                                                                            | 37    | 218   | 300   | mV |
| t <sub>HL(blank)</sub> | Blanking Time for Line Range Detection<br>(must stay below V <sub>LL</sub> for 25 ms before changing to LL)                                               | 13    | 25    | 43    | ms |

## THERMAL SHUTDOWN

|                    |                             |     |    |   |    |
|--------------------|-----------------------------|-----|----|---|----|
| T <sub>LIMIT</sub> | Thermal Shutdown Threshold  | 150 | –  | – | °C |
| H <sub>TEMP</sub>  | Thermal Shutdown Hysteresis | –   | 50 | – | °C |

6. The above specification gives the targeted values of the parameters. The final specification will be available once the complete circuit characterization has been performed.
7. In CrM mode,  $G_{mult} = V_{CS(th)} / [(V_{CTRL} - 0.5) * (1.5/4.0) * V_{MULT}]$ , V<sub>CS(th)</sub> is the CS pin voltage threshold at which DRV pin goes low (end of on-time). K<sub>offset</sub> is set to zero in test mode, otherwise the formula is more complex.

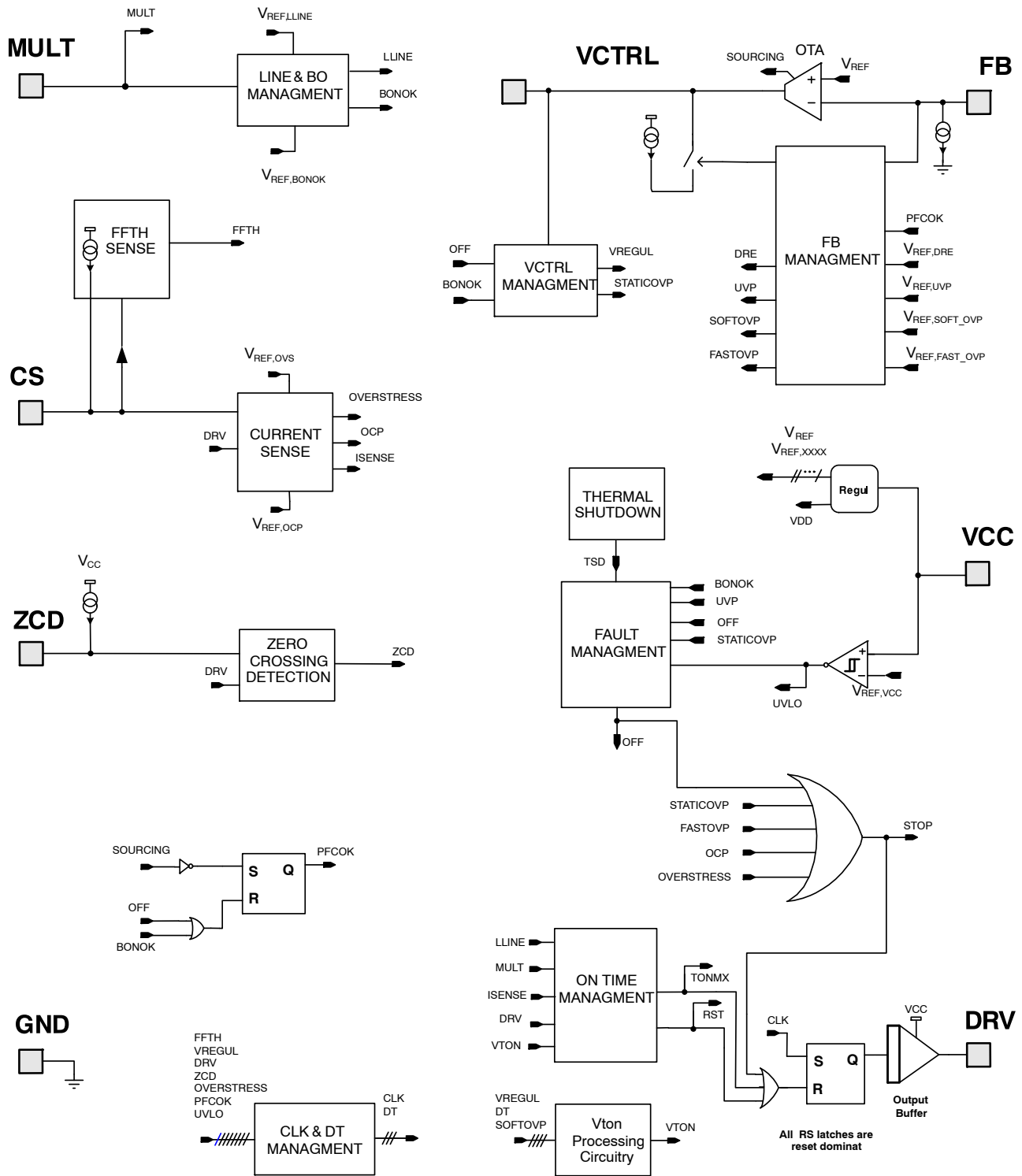


Figure 2. NCL2801 Block Diagram (SOURCING Flag is High When OTA Sources Current, if Sourcing Less Than 1nA SOURCING Flag Goes Low)

## DETAILED OPERATING DESCRIPTION

### Introduction

NCL2801 is designed for working with LED Lighting applications coping with high ripple voltage on bulk capacitor and providing optimized line current THD and good efficiency. In addition, it incorporates protection features for robust operation. More generally, NCL2801 is ideal in systems where cost-effectiveness, reliability, low line current THD, low stand-by power and high efficiency are key requirements:

- **Valley Count Frequency Fold-back:** NCL2801 is designed to drive PFC boost stages in so-called Valley Count Frequency Fold-back (*VCFF*). In high load current condition, the circuit classically operates in *Critical conduction Mode (CrM)* also called 1<sup>st</sup> valley switching. When output power is decreasing, if a threshold is reached (determined by sensing the CS pin impedance during initial power up), a dead time based on a number of valleys is added. The number of valleys will increase, each time a dead time window (based on  $V_{CTRL}$  value) is entered. By construction, this counting process will avoid valley hopping during the mains voltage period. If the output power continues decreasing and the 6<sup>th</sup> valley is reached, extra “analog” dead time will be added based on a voltage ramp (see Figure 4). On-time will be synchronized with a valley. A timer will clamp the total switching period to not exceed 36.5  $\mu$ s (the switching frequency will never go under about 27.4 kHz). The switching frequency depends on output voltage, input voltage, and boost inductor value, and increases as the load power increases. Hysteresis is added to the  $V_{CTRL}$  control windows to avoid valley hopping during steady state conditions. *VCFF* maximizes the efficiency at both nominal and light load. Similarly to *FCCrM* controllers, an internal circuitry allows near-unity power factor even when the switching frequency is reduced.
- **Low Start-up Current:** The start-up consumption of the circuit is minimized to allow the use of high impedance start-up resistors to precharge the  $V_{CC}$  capacitor. Also, the minimum value of the UVLO hysteresis is 6 V to avoid the need for large  $V_{CC}$  capacitors and help shorten the start-up time without the need for excessive dissipation in the start-up circuit. The [*\*C\**] & [*\*D\**] version is preferred in applications where the circuit is fed by an external power source (from an auxiliary power supply or from a downstream converter). After start-up, the high  $V_{CC}$  maximum rating allows a large operating range from 10.5 V up to 27 V.
- **Fast Line / Load Transient Compensation (Dynamic Response Enhancer):** Since PFC stages exhibit low loop bandwidth, abrupt changes in the load or input voltage (e.g. at start-up) may cause excessive over or

under-shoot. This circuit limits possible deviations from the regulation level as follows:

- NCL2801 linearly decays the power delivery to zero when the output voltage exceeds the soft OVP limit (105% of  $V_{REF}$ ) for option [*\*C\**]. Soft OVP feature is disabled on options [*\*A\**] & [*\*B\**]. If this soft OVP is too smooth and the output continues to rise, the circuit immediately (priority to Fast OVP) interrupts the power delivery when the output voltage is 112.5 % above its desired level (Fast OVP) for options [*\*A\**]. Options [*\*B\**] & [*\*C\**] are providing lower Fast OVP thresholds. Fast OVP threshold is higher than Soft OVP threshold for option [*\*C\**].
- While disabled on options [*\*A\**], [*\*C\**] and [*\*E\**] after startup time, NCL2801 has a DRE (Dynamic Response Enhancer) circuitry on options [*\*B\**], [*\*D\**] & [*\*F\**] which dramatically speeds-up the regulation loop when the output voltage goes below 95.5 % of its regulation level. The DRE function is enabled only after the PFC stage has started-up to allow normal soft-start operation to occur. For all the product options, the DRE is active during the start-up phase to accelerate the start-up ( $V_{CTRL}$  pin voltage is brought at its higher value by the by half of the 200- $\mu$ A DRE current source which charges the capacitors of the compensation network)
- **Soft-OVP / Fast-OVP ( Over Voltage Protection)**  
There are cases (for example during a high-load to low-load rapid transition) where the bulk capacitor voltage goes up very rapidly above the voltage regulation level triggering Over-Voltage protection. When the bulk capacitor voltage  $V_{bulk}$  reaches typically 105% of its nominal value, the Soft-OVP protection is triggered, causing the duty-ratio to decrease gradually down to zero. As a consequence,  $V_{bulk}$  decreases and when  $V_{bulk}$  reaches the low level of Soft-OVP threshold (typically 103% of nominal  $V_{bulk}$ ) the protection is released and the voltage regulation loop takes-over. If  $V_{bulk}$  rises faster and reaches the Fast-OVP threshold (typically 107% of nominal  $V_{bulk}$ ), the switching is instantaneously stop (DRV signal is disabled). As a consequence,  $V_{bulk}$  decreases and when the low level of Fast-OVP threshold is reached (typically 103% of nominal  $V_{bulk}$ ) the protection is released and the voltage regulation loop takes-over. Soft-OVP has only one level and can be disabled dependent on product option. Three Fast\_OVP levels are available by product options : typically 107, 110 and 112% of nominal  $V_{bulk}$ . The 112% option is well suited for applications using a low value bulk capacitor where the two-times mains frequency  $V_{bulk}$

ripple voltage is high (in this case Soft-OVP is disabled)

- **Safety Protections:** Permanently monitoring the input and output voltages, the MOSFET current and the die temperature to protect the system from possible over-stress makes the PFC stage extremely robust and reliable. In addition to the OVP protection, the following methods of protection are provided :
  - **Maximum Current Limit:** The circuit senses the MOSFET current and turns off the power switch if the set current limit is exceeded. In addition, the circuit enters a low duty-cycle operation mode when the current reaches 150% of the current limit as a result of the inductor saturation or a short of the bypass diode.
  - **Thermal Shutdown:** An internal thermal circuitry disables the gate drive when the junction temperature exceeds 150°C (typically). The circuit resumes operation once the temperature drops below approximately 100°C (50°C hysteresis).
- **Output Stage Totem Pole:** NCL2801 incorporates a -0.5 A / +0.8 A gate driver to efficiently drive most TO220 or TO247 power MOSFETs.

#### NCL2801 Operation Modes

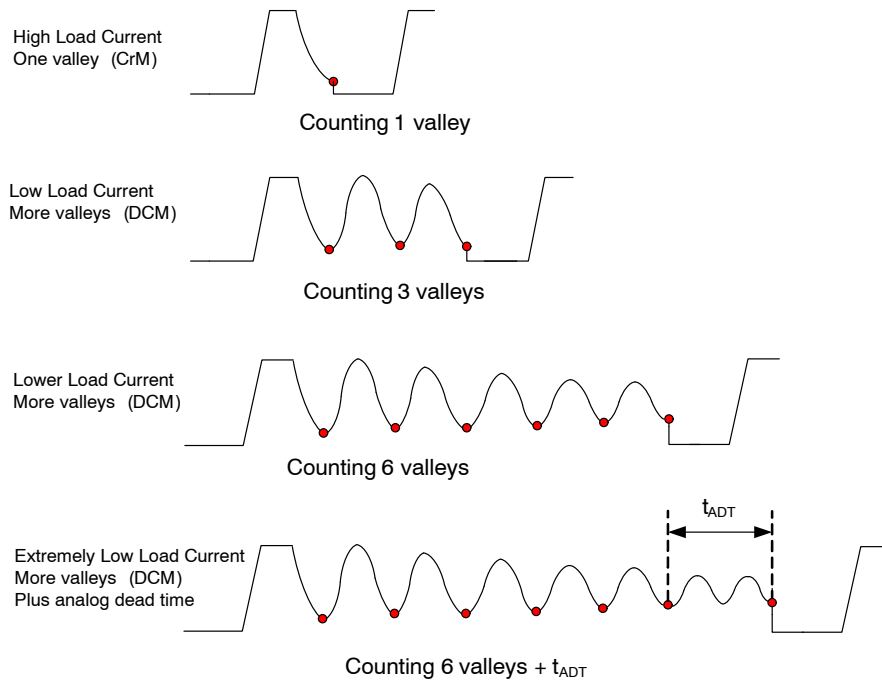
As mentioned, NCL2801 PFC controller implements a Valley Count Frequency Fold-back (*VCFF*) where:

- The circuit operates in classical *Critical* conduction *Mode (CrM)* when output power is high and VCTRL pin voltage greater than a threshold ( $V_{CTRL,th,12}$  for VCTRL decreasing and  $V_{CTRL,th,21}$  for VCTRL increasing) which value is determined by the value the resistance  $R_{CS}$  placed between CS pin and top of Rsense which bottom is connected to GND ( $R_{sense}$  being negligible versus  $R_{CS}$ , it is the  $R_{CS}$  value which is sensed).  $R_{CS}$  value is sensed just before the startup phase (see Table 6).
- When the output power decreases the NCL2801 reduces the operating frequency by means of increasing

valley number count up to 6 valleys (the number of valleys between end of inductor demagnetization and power MOSFET turn-on determines the dead time value). After counting is done, the power MOSFET turns on at drain voltage valley. When 6<sup>th</sup> valley is reached and VCTRL voltage stays under 0.77 V, an extra “analog” dead time is added based on a voltage ramp (see Figure 4). The added analog dead time  $t_{ADT}$  is based on 0.77 V minus VCTRL value.  $t_{ADT}$  will be equal to zero when  $(0.5\text{ V} - V_{CTRL}) = 0\text{ V}$  and will increase monotonically versus VCTRL decreases while VCTRL is under the 0.77 V threshold corresponding to  $V_{CTRL,th,56}$ . The analog dead time added  $t_{ADT}$  will equal typically 20  $\mu\text{s}$  when  $V_{CTRL}=0.5\text{ V}$ .

- When additional “analog” dead time is added, the power MOSFET turn-on will, by default, be synchronized with the falling edge of ZCD signal (valley turn-on) and there will be possible, upon request, of no valley synchronization for the on-time start. The total dead-time (number of valleys and extra dead-time) will not exceed 36.5  $\mu\text{s}$  (A timer will be clamping the dead time).
- When the output power increases, the extra “analog” dead-time plus number of valleys dead time will decrease, according in which VCTRL pin voltage window VCTRL pin voltage is, down to 1<sup>st</sup> valley switching which is the CrM mode. The VCTRL pin voltage window in which VCTRL pin voltage is will be detected with comparators having an hysteresis to avoid valley hopping due to VCTRL pin voltage ripple.
- It will be the responsibility of the application designer not to allow a VCTRL pin voltage ripple (at 2 times the mains frequency) greater than the hysteresis of VCTRL windows.
- Valley hopping can lead to audible noise. The NCL2801 avoids this activity by locking the operating valley before turning on the MOSFET during steady state operation.

## NCL2801



**Figure 3. Valley Switching Operation in CrM and DCM Modes Seen Through Power MOSFET Drain Voltage**

As illustrated in Figure 3, under high load conditions, the boost stage is operating in CrM (only one valley is counted before turning on the power MOSFET). The second example shows a DCM state of operation where 3 valleys have been counted before turning on the power MOSFET. The third example shows a DCM state with lower output power than the previous one where 5 valleys have been counted before turning on the power MOSFET. The fourth example shows how additional dead time is added after 6<sup>th</sup> valley.

### Valley Count Frequency Foldback (VCF)

The turn-on of the power MOSFET is synchronized with the valley of the power MOSFET drain voltage signal by the

means of counting the falling edges of the ZCD signal until the counter reaches the number of valleys set by the window in which the VCTRL pin voltage is (see Figure 4). The 3-bit counter allows to work “Valley synchronized” up to 6 valleys. When the 6<sup>th</sup> valley is reached, and VCTRL is lower than 0.770 V ( $V_{CTRL,th,56} = 0.770$  V whatever frequency foldback threshold setting), an additional analog dead time will be added to the 6 valleys dead time and there will be valley synchronization turn-on of the power MOSFET ( $ADT\_nosync = 0$  by default) based on falling edge of ZCD signal. The total dead-time (number of valleys and extra analog dead-time) will not exceed 36.5  $\mu$ s. As a result of this timer the minimum switching frequency will not go under 27.4 kHz.

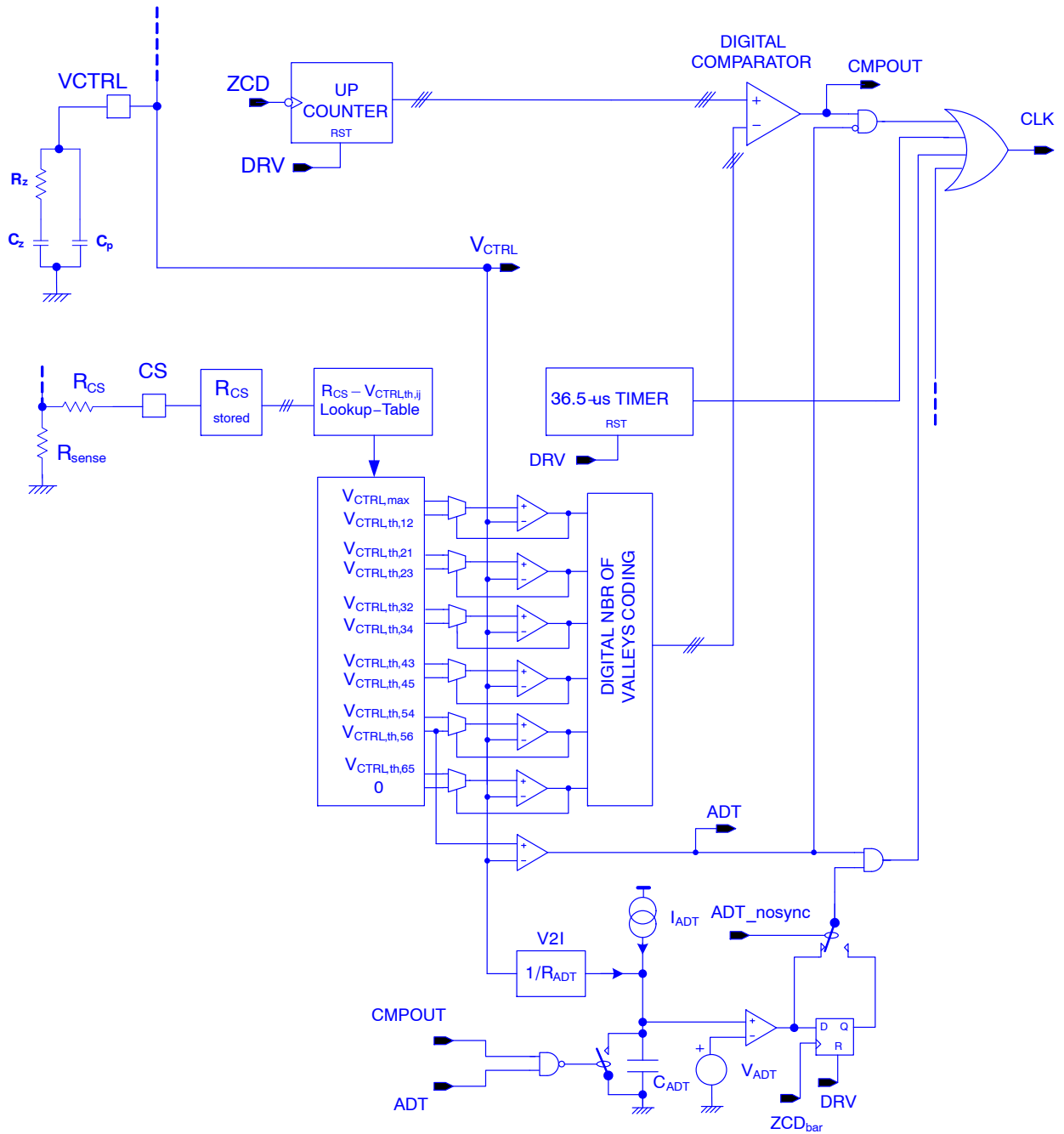


Figure 4. Valley Count Turn-on Block Diagram

This Valley Counting (VC) method avoids “valley hoping” during the half period of mains voltage which is on other designs, the cause of undesired mains current ringing glitches due to the excitation of the input EMI filter by a dead time discontinuity. The NCL2801 circuitry acts so that the PFC controller transitions from the  $n$  valley to  $(n+1)$  valley or from the  $n$  valley to  $(n-1)$  and stays on this valley number is long as the VCTRL pin voltage stays in a the voltage window corresponding to this valley number. If no demagnetization is sensed the power MOSFET will be turned-on after a watchdog timing of 200- $\mu$ s.

The system relies on the counting of ZCD pulses to determine dead-time periods. Should the ZCD pulses diminish in voltage so that the event timing can’t be used, an internal copy of the last reliable first-to-second falling edge timing is substituted for the natural ZCD ring. The substitute timing for a second falling edge is allowed 1 $\mu$ s beyond the recorded value before being asserted. The substitute timing for the third falling edge and afterward is allowed 250 ns beyond the recorded value before a ZCD pulse is asserted.

The NCL2801 PFC controller, depending on the application power output which is correlated with the

VCTRL pin voltage level, starts adding a dead-time  $t_{DT}$ . The system adjusts the on-time  $t_{ON}$  (by means of peak current control) versus  $t_{DT}$  (see Figure 5) and consequently the

output power in order to ensure that the instantaneous mains current remains in phase with the mains instantaneous voltage (creating a unity PF).

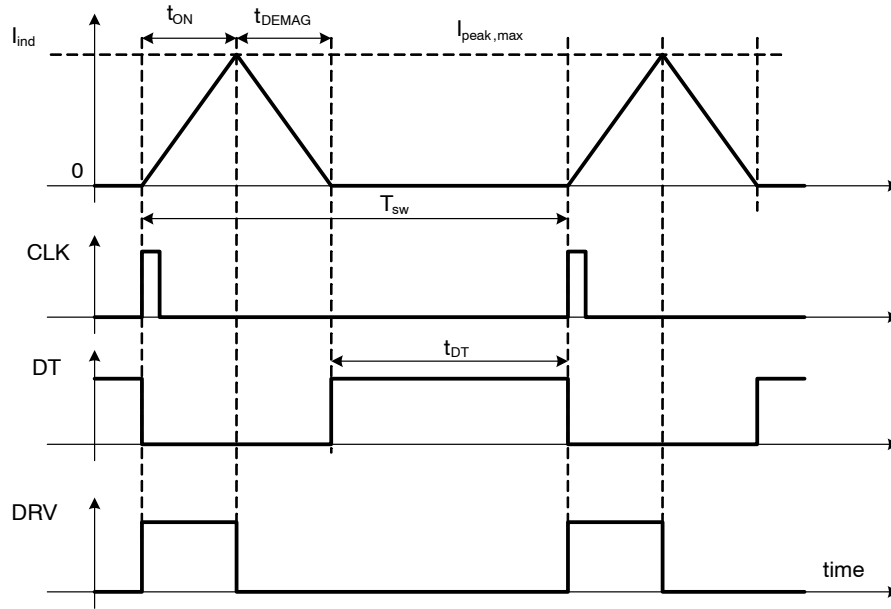


Figure 5. NCL2801 Clock, Dead Time and  $t_{ON}$  waveforms

When the output power is at the maximum available for a given application and the inductor peak current limitation is not triggering, VCTRL pin voltage ( $V_{CTRL}$ ), is above the frequency foldback threshold ( $V_{CTRL,th,21}$ ) making the controller to work in CrM mode. When output power decreases  $V_{CTRL}$  will go under the frequency foldback threshold ( $V_{CTRL,th,12}$ ) and DCM mode will be forced by adding dead time as explained before.

Adding dead-time will naturally decrease the switching frequency, hence the FF (standing for Frequency Foldback) which is part of the name VCFF.

The switching frequency in DCM mode is given by the following equation..

$$F_{SW,DCM} = \frac{1}{t_{DT} + t_{ON} + t_{DEMAG}} \quad (\text{eq. 1})$$

The value of the external resistor placed between CS pin and  $R_{sense}$  will determine the value of the VCTRL pin voltage frequency foldback threshold.

#### CrM-DCM Threshold

For a given application,  $R_{sense}$  and  $R_{mult}$  divider ratio of the resistors bridge connected to MULT pin are set such as

the maximum power is given just under to the maximum VCTRL pin voltage  $V_{CTRL}$  which is 4.5 V. Zero output power will be supplied for  $V_{CTRL}=0.5$  V

For adjusting at which  $V_{CTRL}$  value the transition from CrM to DCM mode will happen, the resistance value between CS pin and GND will be sensed before start-up and its value stored digitally (see Figure 6). The sensed resistance is equal to  $R_{CS}$  plus  $R_{sense}$ , but because  $R_{sense}$  value is much lower than  $R_{CS}$ , it is the  $R_{CS}$  value which will be sensed.

This resistor sense will be done after  $V_{CC,on}$  level is reached and just before the controller starts switching in order to avoid any noise perturbation the sensing (see Figure 6). The  $I_{RCS}$  1-mA ( $\pm 4\%$ ) current source, active when RCS flag is high will generate a voltage drop through  $R_{CS}$  ( $\pm 1\%$ ) resistor and this voltage drop will be compared to internal voltage references to identify which is the  $R_{CS}$  resistor value and set the internal frequency foldback settings.



| $R_{CS} (\Omega)$ | $V_{CTRL,th,12} (V)$ |
|-------------------|----------------------|
| 1000              | 2.19                 |
| 620               | 1.83                 |
| 330               | 1.48                 |
| 150               | 1.12                 |

the X-Axis representing the VCTRL pin voltage. In order to avoid valley hopping due to VCTRL pin voltage ripple, we have included an hysteresis. We can clearly see in Figure

7 that the  $V_{CTRL}$  hysteresis voltage is defined by:  $V_{CTRL,hyst} = V_{CTRL,th43} - V_{CTRL,th,34}$  and more generally by  $V_{CTRL,hyst} = V_{CTRL,th,ij} - V_{CTRL,th,ji}$ . If  $V_{CTRL}$  pin peak-to-peak ripple voltage stays under  $V_{CTRL,hyst}$  there will be no valley hopping.

$V_{CTRL,hyst}$  can be calculated for each frequency foldback option determined by  $R_{CS}$  value from the thresholds specified in Table 7. While the hysteresis between two adjacent valley numbers is constant for one frequency foldback option, it decreases for options having a lower CrM to DCM  $V_{CTRL}$  threshold. This should not be a problem as the two times mains frequency ripple also decreases when  $V_{CTRL}$  pin voltage decreases which

results from output power decrease. We can also mention looking at Figure 7 and the specified frequency foldback thresholds of Table 7 that  $V_{CTRL,th,56}$  which is the  $V_{CTRL}$  threshold at which we force counting 6 valleys, has always the same value. This threshold is also called  $V_{CTRL,ADT}$  because when  $V_{CTRL}$  pin voltage falls under this threshold, an analog dead-time starts to be added to the dead-time determined by counting 6 valleys. The lower  $V_{CTRL}$  pin voltage goes under  $V_{CTRL,ADT}$  threshold, the more analog dead time is added. An example on how the analog dead time can be added is shown in the circuit of Figure 4 and the correspond power MOSFET drain voltage is shown in Figure 3.

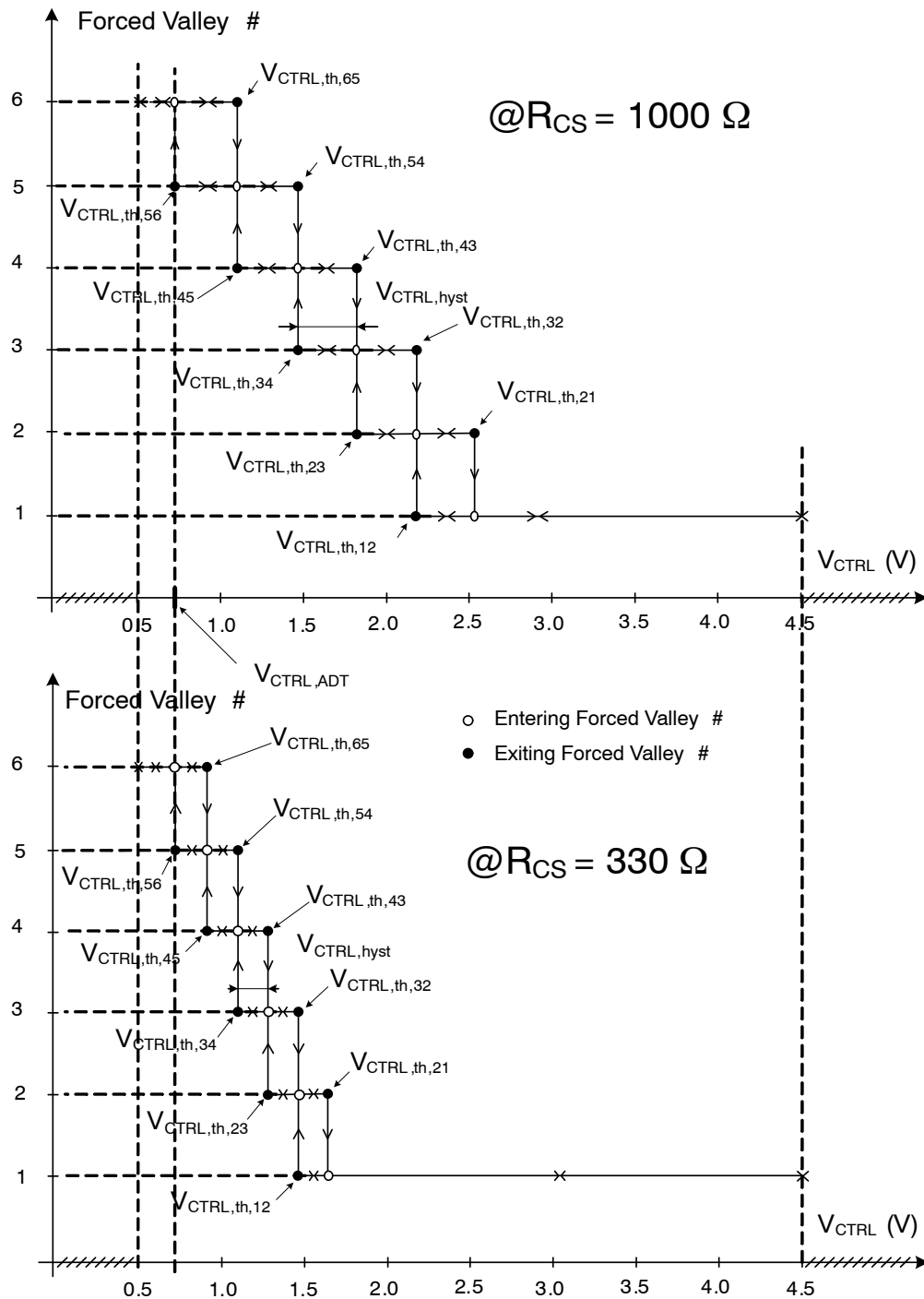


Figure 7. Forced Valley Number versus VCTRL Pin Voltage For a Two Different RCS Values of the Mandatory List {150 Ω, 330 Ω, 620 Ω, 1000 Ω}

### NCL2801 On-time Modulation and $V_{TON}$ Processing Circuit

Let's analyze the ac line current absorbed by the PFC boost stage. The initial inductor current at the beginning of each switching cycle is always zero. The coil current ramps up when the MOSFET is *on*. The slope is  $(V_{in}/L)$  where  $L$  is the coil inductance. At the end of the on-time ( $t_1$ ), the inductor starts to demagnetize. The inductor current ramps down until it reaches zero. The duration of this phase is ( $t_2$ ). In some cases, the system enters then the dead-time ( $t_3$ ) that lasts until the next clock is generated.

One can show that the ac line current is given by:

$$I_{in} = V_{in} \frac{t_1(t_1 + t_2)}{2TL} \quad (\text{eq. 2})$$

Where

$$T = t_1 + t_2 + t_3 \quad (\text{eq. 3})$$

is the switching period and  $V_{in}$  is the ac line rectified voltage.

In light of this equation, we immediately note that  $I_{in}$  is proportional to  $V_{in}$  if  $[t_1(t_1+t_2)/T]$  is a constant.

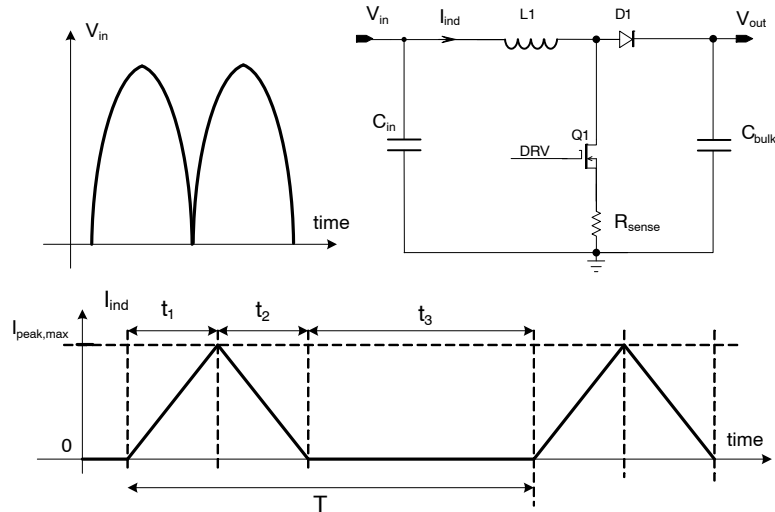


Figure 8. PFC boost converter and Inductor Current in DCM

NCL2801 operates in current control mode. As portrayed by Figure 8 & Figure 10, the MOSFET on-time  $t_1$  results from a current control mode circuitry which is using a dedicated circuitry monitoring  $V_{ctrl}$  and dead-time  $t_3$  ensuring  $[t_1(t_1+t_2)/T]$  is constant and as a result making  $I_{in}$  proportional to  $V_{in}$  (PF=1)

On-time  $t_1$ , also called  $t_{ON}$ , has a high value clamp called  $t_{ON,max}$ , generated by an internal circuitry. This 30- $\mu$ s clamp value is given for maximum  $V_{CTRL}$  pin voltage ( $V_{CTRL}=4.5$  V) but reduces down to 5  $\mu$ s when  $V_{CTRL}$  pin voltage reaches 0.5 V which is its minimum value.

The input current is then proportional to the input voltage. Hence, the ac line current is properly shaped.

One can note that this analysis is also valid in the CrM case. This condition is just a particular case of this functioning where ( $t_3=0$ ), which leads to ( $t_1+t_2=T$ ) and ( $V_{ton}=V_{regul}$ ). That is why the NCL2801 automatically adapts to the conditions and transitions from **DCM<sub>n+1</sub> to DCM<sub>n+1</sub>** and **DCM<sub>n+1</sub> to DCM<sub>n</sub>** without power factor degradation and without discontinuity in the power delivery.

This analysis while carried-out for constant on-time architecture is also valid for the current control architecture

of the NCL2801 because at steady state, what results from a current control is a constant on-time.

### Current Control Mode & THD Enhancer

In order for the mains current to have very good THD, the Current Control Mode depicted in Figure 10 mode is preferred.

To improve the mains current THD, an offset voltage is added to the multiplier output (see Figure 9).

The added offset is equal to  $K_{offset} \cdot V_{ton}$

The role of this offset is to add on-time and this added on-time will be very beneficial close to line zero crossing where, without this offset, the inductor peak current is low and comparable to the inductor negative peak current resulting to zero line current. Adding this offset greatly reduces the time width during which the line current is equal to zero (line voltage cross-over distortion) and by doing improve the line current THD.

A traditional scheme, where the inductor current during on-time multiplied by  $R_{sense}$  is compared to a scaled down rectified mains voltage  $V_{in}$  multiplied by  $V_{ton}$  is used. What may sound strange is the  $V_{ton}$ , but  $V_{ton}$  is equal to  $V_{regul}$  when in CrM.

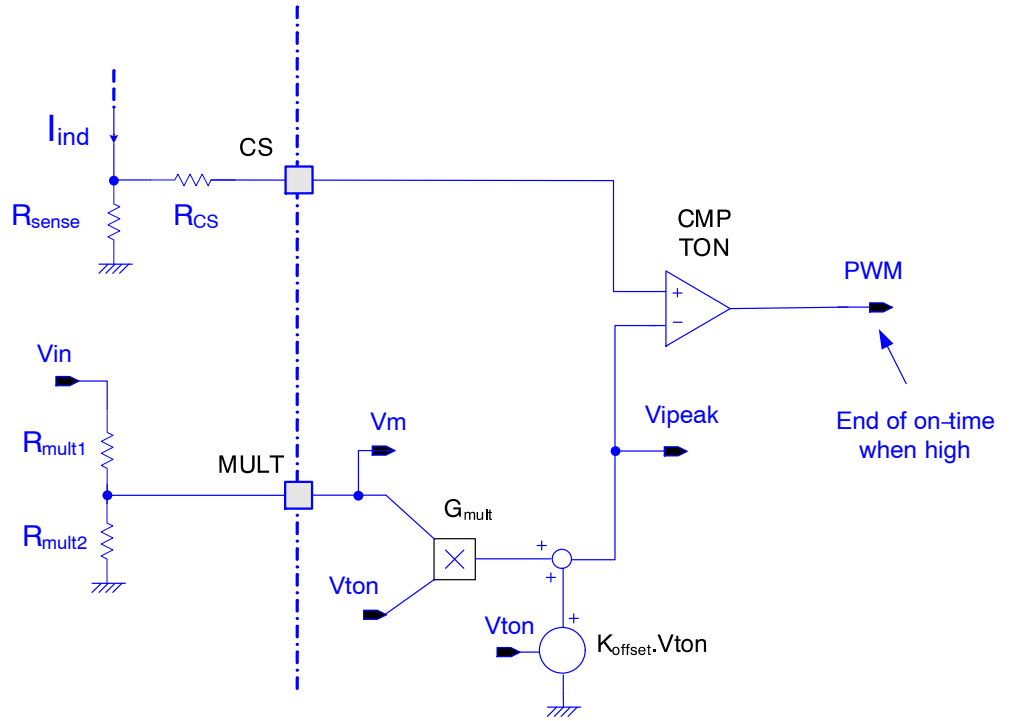


Figure 9. Simplified Current Control Circuit (Max On-Time and Blanking Not Shown)

$$V_{\text{regul}} = (V_{\text{CTRL}} - 0.5\text{V}) \frac{1.5\text{V}}{4.0\text{V}} \quad (\text{eq. 4})$$

The range of  $V_{\text{regul}}$  is equal to 1.5 V and  $V_{\text{regul}}$  operates between 0 V and 1.5 V.

The range of  $V_{\text{CTRL}}$  is equal to 4.0 V and  $V_{\text{CTRL}}$  operates between 0.5 V and 4.5 V.

In DCM mode, the  $V_{\text{ton}}$  input of the multiplier is modified thanks to the  $V_{\text{ton}}$  processing block in order to maintain the mains current proportional to the mains voltage.

It can be demonstrated that the maximum peak inductor current is given by the following equation

$$I_{\text{ind,peak,max}} = \frac{V_{\text{ipeak,max}}}{R_{\text{sense}}} = \frac{(K_m K_{\text{mult}} \sqrt{2} V_{\text{mains,rms}} + K_{\text{offset}}) \cdot V_{\text{TON}}}{R_{\text{sense}}} \quad (\text{eq. 5})$$

From  $I_{\text{ind,peak,max}}$ , assuming we are in CrM we can get the rms line current by :

$$I_{\text{mains,rms}} = \frac{V_{\text{ind,peak,max}}}{2\sqrt{2}} = \frac{(K_m K_{\text{mult}} \sqrt{2} V_{\text{mains,rms}} + K_{\text{offset}}) \cdot V_{\text{TON}}}{2\sqrt{2} R_{\text{sense}}} \quad (\text{eq. 6})$$

Then,

$$P_{\text{mains,rms}} = \frac{(K_m K_{\text{mult}} \sqrt{2} V_{\text{mains,rms}}^2 + K_{\text{offset}} V_{\text{mains,rms}}) \cdot V_{\text{TON}}}{2\sqrt{2} R_{\text{sense}}} \quad (\text{eq. 7})$$

To better see the effect of  $K_{\text{offset}}$  on  $P_{\text{mains,rms}}$  the previous equation can be re-written as follows

$$P_{\text{mains,rms}} = \frac{K_m K_{\text{mult}} V_{\text{mains,rms}}^2 V_{\text{TON}}}{2R_{\text{sense}}} + \frac{K_{\text{offset}} V_{\text{mains,rms}} V_{\text{TON}}}{2\sqrt{2} R_{\text{sense}}} \quad (\text{eq. 8})$$

In both previous equations  $K_{\text{mult}}$  is the multiplier gain and  $K_m$  is given by the following:

$$K_m = \frac{R_{\text{mult2}}}{R_{\text{mult1}} + R_{\text{mult2}}} \quad (\text{eq. 9})$$

It is important to mention that in CrM mode so particularly at max output power,  $V_{\text{TON}} = V_{\text{regul}}$ .

The multiplier gain, for product options having no line level detection ([\*\*B]&[\*\*D]) has a value which does not vary versus  $V_{\text{mains}}$  value.

For product options having line level detection ([\*\*A]&[\*\*C]), the multiplier gain has an High Line value ( $K_{\text{mult,HL}}$ ) and a Low Line value ( $K_{\text{mult,LL}}$ ). These two line

level dependent multiplier gain values act as a two-level line feed forward.

#### NCL2801 Maximum on-time

In order to avoid the on-time to go too high close to line voltage zero crossing, a  $V_{CTRL}$  dependent maximum on time circuitry has been added. The on-time limiting values are linearly depending on  $V_{CTRL}$  pin voltage as follows:

$$30\text{-}\mu\text{s} @ V_{CTRL} = 4.5 \text{ V and } 5\text{-}\mu\text{s} @ V_{CTRL} = 0.55 \text{ V}$$

#### NCL2801 Regulation Block and Output Voltage Control

A trans-conductance error amplifier (OTA) with access to its inverting input (FB pin) and to its output pin ( $V_{CTRL}$  pin) is provided. It features a typical trans-conductance gain of 200  $\mu\text{S}$  and a maximum current capability of  $\pm 20 \mu\text{A}$ . The output voltage of the PFC stage is typically scaled down by a resistors divider and monitored by the OTA inverting input (pin FB). Bias current is minimized (less than 500 nA) to allow the use of a high impedance feed-back network. However, it is high enough so that the pin remains in low state if the pin is not connected.

The output of the error amplifier is brought to pin  $V_{CTRL}$  for external loop compensation. Typically a type-2 network is applied between pin  $V_{CTRL}$  and ground, to set the regulation bandwidth below about 20 Hz and to provide a decent phase boost.

The swing of the error amplifier output is limited within an operating range:

- It is forced above a voltage drop ( $V_F$ ) by a dedicated circuitry.
- It is clamped not to exceed 4.0 V + the same  $V_F$  voltage drop.

The  $V_F$  value is 0.5 V typically.

The regulated output voltage  $V_{bulk}$  uses an internal reference voltage  $V_{REF} = 2.5 \text{ V}$ .

The regulated  $V_{bulk}$  voltage (its average value in case of important ripple) will be equal to  $V_{REF}$  multiplied by the dividing factor given by the resistor bridge placed between  $V_{bulk}$  and FB pin, resulting for example in  $V_{bulk} = 395 \text{ V}$ .

Given the low bandwidth of the regulation loop, abrupt variations of the load, may result in excessive over or under-shoot. Over-shoot is limited by the Over-Voltage Protection (OVP) connected to FB pin (Feedback).

Optionally, NCL2801 embeds a “Dynamic Response Enhancer” circuitry (DRE) that limits under-shoots. The DRE works during startup phase by injecting current into the  $V_{CTRL}$  pin which rises  $V_{CTRL}$  pin voltage and allows more current to charge the bulk capacitor. After the startup phase, when internal PFCOK flag goes high, the DRE is disabled on some options, but is enabled in other product

options. For the product options where the DRE is enabled, an internal comparator monitors the FB pin voltage ( $V_{FB}$ ) and when  $V_{FB}$  is lower than 95.5% of its nominal value, it connects the 220- $\mu\text{A}$  current source to  $V_{CTRL}$  pin in order to speed-up the charge of the compensation network. Effectively this appears as a 10x increase in the loop gain.

The circuit also detects overshoot using the Soft OVP circuitry and immediately reduces the power delivery when the output voltage exceeds a value which is product option dependent.

The error Operational Transconductance Amplifier OTA and the OVP and DRE comparators share the same input information. Based on the typical value of their parameters and if  $V_{bulk,nom}$  is the bulk nominal voltage value (e.g., 400 V), we can deduce:

- Output Regulation Level:  $V_{bulk,nom}$
- Output DRE Level:  $V_{bulk,dre} = 95.5\% \cdot V_{bulk,nom}$
- Output Soft OVP Level:  $V_{bulk,sovp} = X\% \cdot V_{bulk,nom}$
- Output Fast OVP level:  $V_{bulk,fovp} = Y\% \cdot V_{bulk,nom}$

NOTE: Note: X% and Y% are product option dependent

#### Current Sense and Current Control

The power MOSFET current  $I_{ind}$  is sensed during the on-time phase by the resistor  $R_{sense}$  inserted between the MOSFET source and ground (see Figure 10). The voltage  $R_{sense} \cdot I_{ind}$  after a proper leading edge blanking ( $t_{LEB,OC}$  and  $t_{LEB,OVS}$ ) starting from the power MOSFET rising edge drive signal (DRV) is compared to internal over-current protection (OCP) and overstress protection (OVS) internal references (namely  $V_{CS(th)}$  and  $V_{CS,OVS(th)}$ ) which when triggered ends the on-time for OCP or stops the switching during 800  $\mu\text{s}$  for OVS. The voltage  $R_{sense} \cdot I_{ind}$  is also low-pass filtered ( $R=20 \text{ k}\Omega$ ,  $C=20 \text{ pF}$  see Figure 10), leading edge blanked and compared to the multiplier output voltage to generate the end of the on-time which is typical of a current mode control (see Figure 10).

In order to improve the THD of the mains current, a  $V_{ton}$  dependent offset at the output of the multiplier and a TONMAX processing block have been added (see Figure 10).

$V_{ton}$  is one of the inputs of the multiplier for helping improve THD in DCM mode (Frequency Foldback).

$V_{ton}$  is equal to  $V_{regul}$  which is proportional to the  $V_{CTRL}$  pin voltage when in CrM mode.

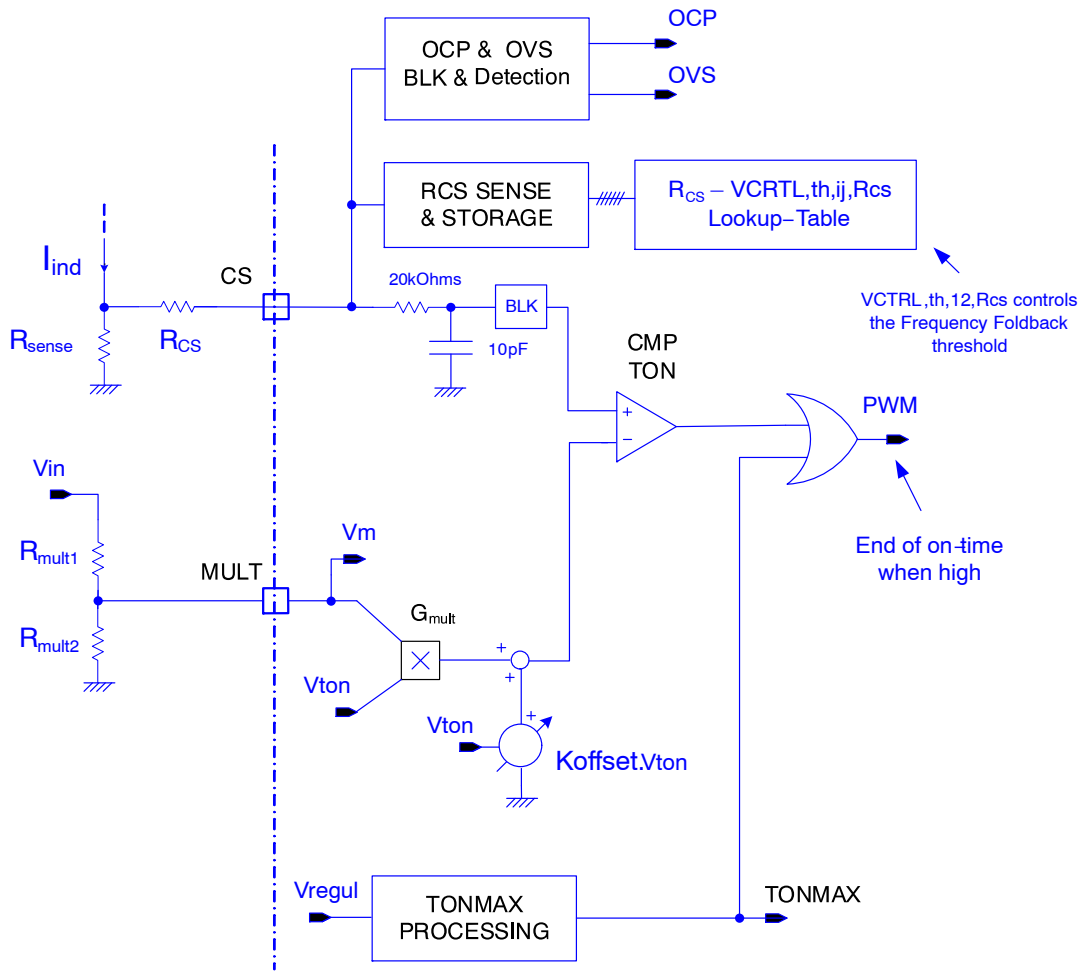


Figure 10. PWM Circuit Showing Current Control Mode With a New MULT Pin

### Zero Current Detection (ZCD)

The ZCD pin features a classical and robust ZCD detection based on sensing the auxiliary winding voltage as shown in Figure 11. The ZCD pin voltage is clamped high at  $V_{CC}$  plus a diode  $V_f$  (0.7 V) and clamped low at minus a diode  $V_f$  (-0.7 V) and then compared to ZCD thresholds voltages  $V_{ZCD,th,H}$  and  $V_{ZCD,th,L}$  (see Table 6).

When no signal is received that triggers the ZCD comparator to indicate the end of inductor demagnetization, an internal 200- $\mu$ s watchdog timer initiates the next drive pulse.

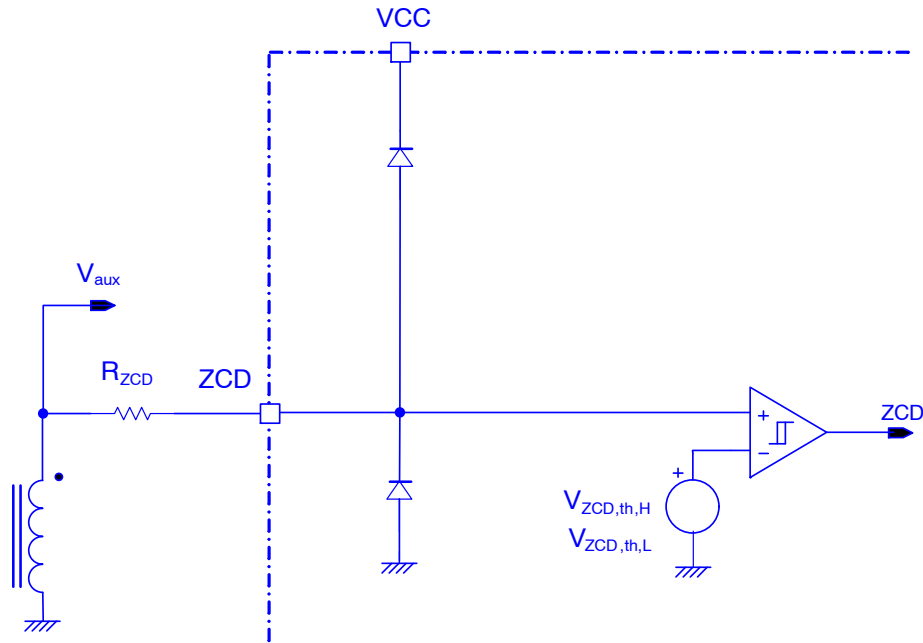


Figure 11. Zero Current Detection (ZCD) Circuitry

**Brown-Out Detection) – (Options [\*\*A], [\*\*B])**

Thanks to the line voltage scaled-down by  $K_m$  and rectified available on MULT-pin ( $V_m$ ) a Brown-Out feature is available on options [\*\*A], [\*\*B].

$$V_m(t) = K_m \cdot V_{in}(t) \quad (\text{eq. 10})$$

With

$$K_m = \frac{R_{mult2}}{R_{mult1} + R_{mult2}} \quad (\text{eq. 11})$$

The  $V_{MULT}$  voltage is sensed and when eventually  $V_{MULT}$  falls under Brown-out internal reference voltage  $V_{BOL}$  for 50 ms, BONOK flag will be set to 1. After BONOK flag is set to 1, drive is not disabled, instead, a 30- $\mu$ A current source ( $I_{VCTRL(BO)}$ ) is applied to VCTRL pin to gradually reduce  $V_{CTRL}$ . As a result, the circuit only stops pulsing when the STATICOVF function is activated. At that moment, the circuit stops switching. This method limits any risk of false triggering.

The input of the PFC stage has some impedance that leads to some sag of the input voltage when the input current is large. If the PFC stage suddenly stops while a high current is drawn from the mains, the abrupt decay of the current may make the input voltage rise and the circuit detect a correct line level. Instead, the gradual decrease of  $V_{CTRL}$  avoids a line current discontinuity and limits the risk of false triggering.

The line voltage ( $V_{line,BO,H}$ ) at which the controller starts switching which can be called **brown-in** and is given by the following equation:

$$V_{line,BO,H} = V_{line,Brown-in} = \frac{V_{BOH}}{K_m \sqrt{2}} \quad (\text{eq. 12})$$

The line voltage ( $V_{line,BO,L}$ ) at which the controller starts reducing on-time until it stops switching which can be called **brown-out** and is given by:

$$V_{line,BO,L} = V_{line,Brown-out} = \frac{V_{BOL}}{K_m \sqrt{2}} \quad (\text{eq. 13})$$

It has to be reminded that while changing  $K_m$  by changing the  $R_{mult}$  resistors dividing ratio can help to shift up or down the line brown-in and brown-out levels,  $K_m$  determines also the internal gain of the controller, together with  $R_{sense}$  and  $K_{mult}$  (multiplier gain), so care must be taken at adjusting  $R_{sense}$  accordingly to the  $K_m$  adjustment.

**Line Level Detection and 2-Level Line Feed-Forward- (Options [\*\*A], [\*\*C])**

For product options [\*\*A], [\*\*C], the line level detection (High Line or Low Line) feature together with a two-level line feed forward is activated and operates as described here after.

$V_{MULT}$  pin voltage  $V_{MULT}$  is used to sense the line voltage and apply a two-level line feed-forward.

The  $V_{MULT}$  voltage is compared to a  $V_{HL}$  internal voltage reference. If  $V_{MULT}$  exceeds  $V_{HL}$ , the circuit detects a High-Line state (LLINE flag is set to 0) and the multiplier gain is set to value corresponding to High Line which is  $K_{mult,HL}$ . Once this occurs, if  $V_{MULT}$  remains below  $V_{LL}$  for 25 ms, the circuit detects a Low-Line state ( $V_{HL(hyst)}$  hysteresis) and the multiplier gain is set to  $K_{mult,LL}$ .

At startup, the circuit is in High-Line state (LLINE flag is set to 0) and then  $V_{MULT}$  will be used to determine the High-Line or Low-Line state.

The line range detection circuit allows more optimal loop gain control for universal (wide input mains) applications by adjusting the multiplier gain value versus line voltage status (High Line or Low Line).

For the options [\*\*B], [\*\*D], no line feedforward action is taken based on the line level and the multiplier gain remains set at  $K_{mult}$  whatever line level.

The High Line and Low Line thresholds, respectively  $V_{line,HL}$  and  $V_{line,LL}$  are given by the following equations:

$$V_{line,HL,rms} = \frac{V_{HL}}{K_m \sqrt{2}} \quad (\text{eq. 14})$$

$$V_{line,LL,rms} = \frac{V_{LL}}{K_m \sqrt{2}} \quad (\text{eq. 15})$$

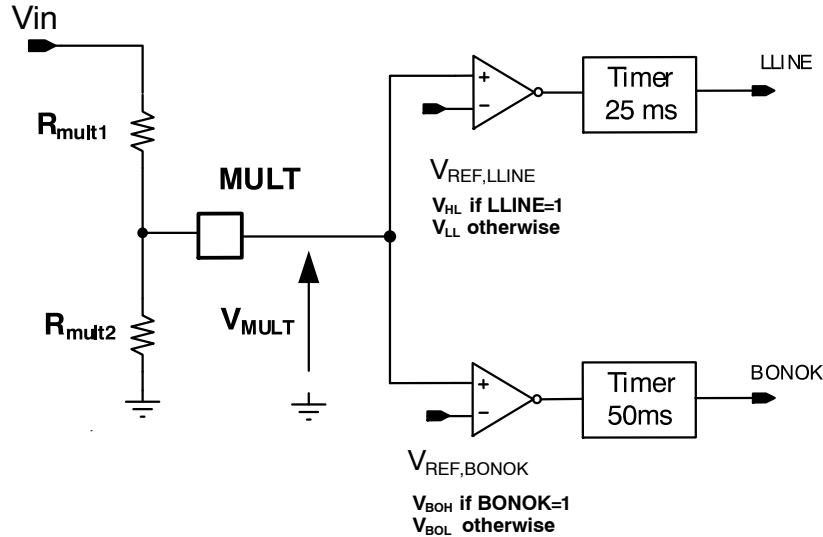


Figure 12. Input Line Sense and Brown-out Monitoring

#### Thermal Shut-Down (TSD)

An internal circuitry sensing the silicon temperature disables the circuit gate drive and keeps the power switch off when the junction temperature exceeds 150°C. The output stage is then enabled once the temperature drops below about 100°C (50°C hysteresis).

The temperature shutdown remains active as long as the circuit is not reset, that is, as long as  $V_{CC}$  is higher than a reset threshold.

#### Output Drive Section

The output stage contains a totem pole optimized to minimize the cross conduction current during high frequency operation. Its high current capability (–500 mA/+800 mA) allows it to effectively drive high gate charge power MOSFET.

#### OFF Mode

As previously mentioned, the circuit turns off when one of the following faults is detected:

- Incorrect feeding of the circuit (“UVLO” high when  $V_{CC} < V_{CC(off)}$ ,  $V_{CC(off)}$ ).
- Excessive die temperature detected by the thermal shutdown
- STATICOV (see Figure 2)

Generally speaking, the circuit turns off when the conditions are not proper for desired operation. In this mode, the controller stops operating. The major part of the circuit sleeps and its consumption is minimized.

More specifically, when the circuit is in OFF state:

- The drive output is kept low
- All the blocks are off except:
  - ♦ The UVLO circuitry that keeps monitoring the  $V_{CC}$  voltage and controlling the start-up current source accordingly.
  - ♦ The TSD (thermal shutdown)
- $V_{ctrl}$  is grounded so that when the fault is removed, the device starts-up under the soft start mode.
- The internal “PFCOK” signal is grounded.
- The output of the “ $V_{ton}$  processing block” is grounded

#### Failure detection

When manufacturing a power supply, elements can be accidentally shorted or improperly soldered. Such failures can also happen to occur later on because of the components fatigue or excessive stress, soldering defaults or external interactions. In particular, adjacent pins of controllers can be shorted; a pin can be grounded or badly connected. Such open/short situations are generally required not to cause fire, smoke or hazardous conditions. NCL2801 integrate functions that ease meeting this requirement. Among them, we can list:

- ♦ Fault of the GND connection  
If the GND pin is not connected, internal circuitry detects it and if such a fault is detected for 200  $\mu$ s, the circuit stops operating.
- ♦ Fault of the FB connection  
If the FB pin is left open because for example of bad

## NCL2801

soldering, an internal pull down current source pulls down the FB voltage under the UVP threshold and the controller is turned off.

◆ Detection the ZCD pin improper connection

If the ZCD pin is floating or shorted to GND it is detected by internal circuitry and the circuit stops operating.

◆ Boost or bypass diode short

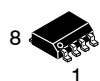
The controller addresses the short situations of the boost and bypass diodes (a bypass diode is generally placed between the input and output high-voltage rails to divert this inrush current). Practically, the overstress protection is implemented to detect such conditions and forces a low duty-cycle operation until the fault is gone.

**Table 8. NCL2801 ORDERING TABLE**

| Ordering Part No. | Soft OVP | Fast OVP (%) | V <sub>CC</sub> Start (V) | DRE (after start) | DRE (during start) | Brown Out | Line Range Detect | Package          | Shipping         |
|-------------------|----------|--------------|---------------------------|-------------------|--------------------|-----------|-------------------|------------------|------------------|
| NCL2801CDADR2G    | X        | 107          | 12.5                      | X                 | X                  | X         | X                 | SOIC-8 (Pb-Free) | 2500/Tape & Reel |
| NCL2801CDBDR2G    | X        | 107          | 12.5                      | X                 | X                  | X         |                   |                  |                  |
| NCL2801CFADR2G    | X        | 107          | 10.5                      | X                 | X                  | X         | X                 |                  |                  |

# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

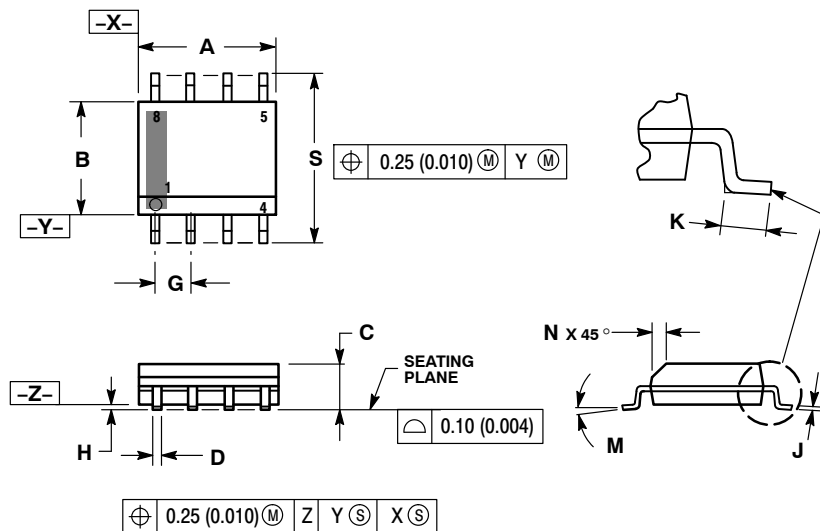
ON Semiconductor®



SCALE 1:1

SOIC-8 NB  
CASE 751-07  
ISSUE AK

DATE 16 FEB 2011

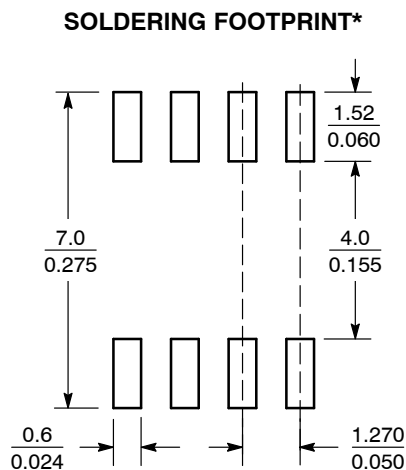


## NOTES:

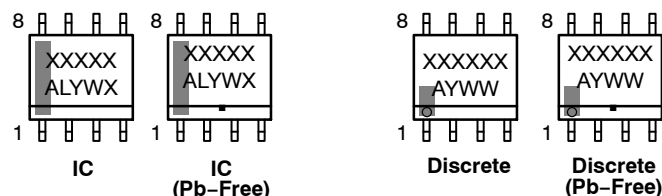
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

| DIM | MILLIMETERS |      | INCHES    |       |
|-----|-------------|------|-----------|-------|
|     | MIN         | MAX  | MIN       | MAX   |
| A   | 4.80        | 5.00 | 0.189     | 0.197 |
| B   | 3.80        | 4.00 | 0.150     | 0.157 |
| C   | 1.35        | 1.75 | 0.053     | 0.069 |
| D   | 0.33        | 0.51 | 0.013     | 0.020 |
| G   | 1.27 BSC    |      | 0.050 BSC |       |
| H   | 0.10        | 0.25 | 0.004     | 0.010 |
| J   | 0.19        | 0.25 | 0.007     | 0.010 |
| K   | 0.40        | 1.27 | 0.016     | 0.050 |
| M   | 0°          | 8°   | 0°        | 8°    |
| N   | 0.25        | 0.50 | 0.010     | 0.020 |
| S   | 5.80        | 6.20 | 0.228     | 0.244 |

## GENERIC MARKING DIAGRAM\*



SCALE 6:1 (mm/inches)



XXXXXX = Specific Device Code  
A = Assembly Location  
L = Wafer Lot  
Y = Year  
W = Work Week  
▪ = Pb-Free Package

XXXXXX = Specific Device Code  
A = Assembly Location  
Y = Year  
WW = Work Week  
▪ = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## STYLES ON PAGE 2

|                  |             |                                                                                                                                                                                  |
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| DESCRIPTION:     | SOIC-8 NB   | PAGE 1 OF 2                                                                                                                                                                      |

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**SOIC-8 NB**  
**CASE 751-07**  
**ISSUE AK**

DATE 16 FEB 2011

|                                                                                                                                                                                                   |                                                                                                                                                                                          |                                                                                                                                                                                    |                                                                                                                                                                                                        |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>STYLE 1:</b><br>PIN 1. EMITTER<br>2. COLLECTOR<br>3. COLLECTOR<br>4. EMITTER<br>5. EMITTER<br>6. BASE<br>7. BASE<br>8. EMITTER                                                                 | <b>STYLE 2:</b><br>PIN 1. COLLECTOR, DIE, #1<br>2. COLLECTOR, #1<br>3. COLLECTOR, #2<br>4. COLLECTOR, #2<br>5. BASE, #2<br>6. EMITTER, #2<br>7. BASE, #1<br>8. EMITTER, #1               | <b>STYLE 3:</b><br>PIN 1. DRAIN, DIE #1<br>2. DRAIN, #1<br>3. DRAIN, #2<br>4. DRAIN, #2<br>5. GATE, #2<br>6. SOURCE, #2<br>7. GATE, #1<br>8. SOURCE, #1                            | <b>STYLE 4:</b><br>PIN 1. ANODE<br>2. ANODE<br>3. ANODE<br>4. ANODE<br>5. ANODE<br>6. ANODE<br>7. ANODE<br>8. COMMON CATHODE                                                                           |
| <b>STYLE 5:</b><br>PIN 1. DRAIN<br>2. DRAIN<br>3. DRAIN<br>4. DRAIN<br>5. GATE<br>6. GATE<br>7. SOURCE<br>8. SOURCE                                                                               | <b>STYLE 6:</b><br>PIN 1. SOURCE<br>2. DRAIN<br>3. DRAIN<br>4. SOURCE<br>5. SOURCE<br>6. GATE<br>7. GATE<br>8. SOURCE                                                                    | <b>STYLE 7:</b><br>PIN 1. INPUT<br>2. EXTERNAL BYPASS<br>3. THIRD STAGE SOURCE<br>4. GROUND<br>5. DRAIN<br>6. GATE 3<br>7. SECOND STAGE Vd<br>8. FIRST STAGE Vd                    | <b>STYLE 8:</b><br>PIN 1. COLLECTOR, DIE #1<br>2. BASE, #1<br>3. BASE, #2<br>4. COLLECTOR, #2<br>5. COLLECTOR, #2<br>6. EMITTER, #2<br>7. EMITTER, #1<br>8. COLLECTOR, #1                              |
| <b>STYLE 9:</b><br>PIN 1. EMITTER, COMMON<br>2. COLLECTOR, DIE #1<br>3. COLLECTOR, DIE #2<br>4. EMITTER, COMMON<br>5. EMITTER, COMMON<br>6. BASE, DIE #2<br>7. BASE, DIE #1<br>8. EMITTER, COMMON | <b>STYLE 10:</b><br>PIN 1. GROUND<br>2. BIAS 1<br>3. OUTPUT<br>4. GROUND<br>5. GROUND<br>6. BIAS 2<br>7. INPUT<br>8. GROUND                                                              | <b>STYLE 11:</b><br>PIN 1. SOURCE 1<br>2. GATE 1<br>3. SOURCE 2<br>4. GATE 2<br>5. DRAIN 2<br>6. DRAIN 2<br>7. DRAIN 1<br>8. DRAIN 1                                               | <b>STYLE 12:</b><br>PIN 1. SOURCE<br>2. SOURCE<br>3. SOURCE<br>4. GATE<br>5. DRAIN<br>6. DRAIN<br>7. DRAIN<br>8. DRAIN                                                                                 |
| <b>STYLE 13:</b><br>PIN 1. N.C.<br>2. SOURCE<br>3. SOURCE<br>4. GATE<br>5. DRAIN<br>6. DRAIN<br>7. DRAIN<br>8. DRAIN                                                                              | <b>STYLE 14:</b><br>PIN 1. N-SOURCE<br>2. N-GATE<br>3. P-SOURCE<br>4. P-GATE<br>5. P-DRAIN<br>6. P-DRAIN<br>7. N-DRAIN<br>8. N-DRAIN                                                     | <b>STYLE 15:</b><br>PIN 1. ANODE 1<br>2. ANODE 1<br>3. ANODE 1<br>4. ANODE 1<br>5. CATHODE, COMMON<br>6. CATHODE, COMMON<br>7. CATHODE, COMMON<br>8. CATHODE, COMMON               | <b>STYLE 16:</b><br>PIN 1. EMITTER, DIE #1<br>2. BASE, DIE #1<br>3. EMITTER, DIE #2<br>4. BASE, DIE #2<br>5. COLLECTOR, DIE #2<br>6. COLLECTOR, DIE #2<br>7. COLLECTOR, DIE #1<br>8. COLLECTOR, DIE #1 |
| <b>STYLE 17:</b><br>PIN 1. VCC<br>2. V2OUT<br>3. V1OUT<br>4. TXE<br>5. RXE<br>6. VEE<br>7. GND<br>8. ACC                                                                                          | <b>STYLE 18:</b><br>PIN 1. ANODE<br>2. ANODE<br>3. SOURCE<br>4. GATE<br>5. DRAIN<br>6. DRAIN<br>7. CATHODE<br>8. CATHODE                                                                 | <b>STYLE 19:</b><br>PIN 1. SOURCE 1<br>2. GATE 1<br>3. SOURCE 2<br>4. GATE 2<br>5. DRAIN 2<br>6. MIRROR 2<br>7. DRAIN 1<br>8. MIRROR 1                                             | <b>STYLE 20:</b><br>PIN 1. SOURCE (N)<br>2. GATE (N)<br>3. SOURCE (P)<br>4. GATE (P)<br>5. DRAIN<br>6. DRAIN<br>7. DRAIN<br>8. DRAIN                                                                   |
| <b>STYLE 21:</b><br>PIN 1. CATHODE 1<br>2. CATHODE 2<br>3. CATHODE 3<br>4. CATHODE 4<br>5. CATHODE 5<br>6. COMMON ANODE<br>7. COMMON ANODE<br>8. CATHODE 6                                        | <b>STYLE 22:</b><br>PIN 1. I/O LINE 1<br>2. COMMON CATHODE/VCC<br>3. COMMON CATHODE/VCC<br>4. I/O LINE 3<br>5. COMMON ANODE/GND<br>6. I/O LINE 4<br>7. I/O LINE 5<br>8. COMMON ANODE/GND | <b>STYLE 23:</b><br>PIN 1. LINE 1 IN<br>2. COMMON ANODE/GND<br>3. COMMON ANODE/GND<br>4. LINE 2 IN<br>5. LINE 2 OUT<br>6. COMMON ANODE/GND<br>7. COMMON ANODE/GND<br>8. LINE 1 OUT | <b>STYLE 24:</b><br>PIN 1. BASE<br>2. EMITTER<br>3. COLLECTOR/ANODE<br>4. COLLECTOR/ANODE<br>5. CATHODE<br>6. CATHODE<br>7. COLLECTOR/ANODE<br>8. COLLECTOR/ANODE                                      |
| <b>STYLE 25:</b><br>PIN 1. VIN<br>2. N/C<br>3. REXT<br>4. GND<br>5. IOUT<br>6. IOUT<br>7. IOUT<br>8. IOUT                                                                                         | <b>STYLE 26:</b><br>PIN 1. GND<br>2. dv/dt<br>3. ENABLE<br>4. ILIMIT<br>5. SOURCE<br>6. SOURCE<br>7. SOURCE<br>8. VCC                                                                    | <b>STYLE 27:</b><br>PIN 1. ILIMIT<br>2. OVLO<br>3. UVLO<br>4. INPUT+<br>5. SOURCE<br>6. SOURCE<br>7. SOURCE<br>8. DRAIN                                                            | <b>STYLE 28:</b><br>PIN 1. SW_TO_GND<br>2. DASIC_OFF<br>3. DASIC_SW_DET<br>4. GND<br>5. V_MON<br>6. VBULK<br>7. VBULK<br>8. VIN                                                                        |
| <b>STYLE 29:</b><br>PIN 1. BASE, DIE #1<br>2. EMITTER, #1<br>3. BASE, #2<br>4. EMITTER, #2<br>5. COLLECTOR, #2<br>6. COLLECTOR, #2<br>7. COLLECTOR, #1<br>8. COLLECTOR, #1                        | <b>STYLE 30:</b><br>PIN 1. DRAIN 1<br>2. DRAIN 1<br>3. GATE 2<br>4. SOURCE 2<br>5. SOURCE 1/DRAIN 2<br>6. SOURCE 1/DRAIN 2<br>7. SOURCE 1/DRAIN 2<br>8. GATE 1                           |                                                                                                                                                                                    |                                                                                                                                                                                                        |

|                         |                    |                                                                                                                                                                                     |
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